STM8L050J3



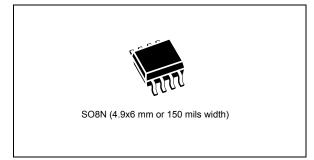
Value line, 8-bit ultra-low-power MCU, 8-Kbyte Flash, 256-byte data EEPROM, RTC, timers, USART, I2C, SPI, ADC, comparators

Datasheet - production data

Features

- Operating conditions
 - Operating power supply: 1.8 V to 3.6 V
 Temperature range: -40 °C to 125 °C
- Low-power features
 - 5 low-power modes: Wait, Low-power run (5.1 μA), Low-power wait (3 μA), Activehalt with RTC (1.3 μA), Halt (350 nA)
 - Ultra-low leakage per I/O: 50 nA
 - Fast wakeup from Halt: 5 μs
- Advanced STM8 core
 - Harvard architecture and 3-stage pipeline
 - Max freq: 16 MHz, 16 CISC MIPS peak
 - Up to 6 external interrupt sources
- · Reset and supply management
 - Low power, ultra-safe BOR reset with 5 selectable thresholds
 - Ultra-low power POR/PDR
 - Programmable voltage detector (PVD)
- Clock management
 - 32 kHz and 1 to 16 MHz crystal oscillators
 - Internal 16 MHz factory-trimmed RC
 - Internal 38 kHz low consumption RC
 - Clock security system
- Low-power RTC
 - BCD calendar with alarm interrupt
 - Digital calibration with +/- 0.5 ppm accuracy
 - LSE security system
 - Auto-wakeup from Halt w/ periodic interrupt
- Memories
 - 8 Kbytes of Flash program memory and 256 bytes of data EEPROM with ECC
 - Flexible write and read protection modes
 - 1 Kbyte of RAM

This is information on a product in full production.



- DMA
 - 4 channels supporting ADC, SPI, I2C, USART, timers
 - 1 channel for memory-to-memory
- 12-bit ADC up to 1 Msps/4 channels
 - Internal reference voltage
- Timers
 - Two 16-bit timers with 2 channels (used as IC, OC, PWM), quadrature encoder
 - One 8-bit timer with 7-bit prescaler
 - 2 watchdogs: 1 Window, 1 Independent
 - Beeper timer with 1, 2 or 4 kHz frequencies
- Communication interfaces
 - Synchronous serial interface (SPI)
 - Fast I2C 400 kHz SMBus and PMBus
 - USART
- Up to 6 I/Os, all mappable on interrupt vectors
- Development support
 - Fast on-chip programming and nonintrusive debugging with SWIM
 - Bootloader using USART
- Two ultra-low-power comparators
 - One with fixed threshold and another one with rail to rail

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Wakeup capability

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Introduction STM8L050J3

Introduction

This document describes the features, pinout, mechanical data and ordering information for the STM8L050J3 microcontroller with 8-Kbyte Flash memory.

For further details on the STMicroelectronics low density family please refer to Section 2.2: Ultra-low-power continuum.

For detailed information on device operation and registers, refer to the STM8L050J3, STM8L051F3, STM8L052C6, STM8L052R8 MCUs and STM8L151/L152, STM8L162, STM8AL31, STM8AL3L lines reference manual (RM0031).

For information on to the Flash program memory and data EEPROM, refer to the How to program STM8L and STM8AL Flash program memory and data EEPROM programming manual (PM0054).

For information on the debug module and SWIM (single wire interface module), refer to the STM8 SWIM communication protocol and debug module user manual (UM0470).

For information on the STM8 core, refer to the STM8 CPU programming manual (PM0044).

The low density value line devices, like STM8L050J3, provide the following benefits:

- Integrated system
 - 8 Kbytes of low-density embedded Flash program memory
 - 256 bytes of data EEPROM
 - 1 Kbyte of RAM
 - Internal high-speed and low-power low speed RC
 - Embedded reset
- Ultra-low-power consumption
 - 1 µA in Active-halt mode
 - Clock gated system and optimized power management
 - Capability to execute from RAM for Low-power wait mode and Low-power run mode
- Advanced features

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- Up to 16 MIPS at 16 MHz CPU clock frequency
- Direct memory access (DMA) for memory-to-memory or peripheral-to-memory access
- Short development cycles
 - Application scalability across a common family product architecture with compatible pinout, memory map and modular peripherals
 - Wide choice of development tools

These features make STM8L050J3 suitable for a wide range of consumer and mass market applications.

Refer to Table 1: STM8050J3 features and peripheral counts and Section 3: Functional overview for an overview of the complete range of peripherals proposed in this family.

Figure 1 shows STM8L050J3 block diagram.

STM8L050J3 Description

2 Description

STM8L050J3 is member of the STM8L ultra-low-power 8-bit family.

STM8L050J3 features an enhanced STM8 CPU core providing increased processing power (up to 16 MIPS at 16 MHz) while maintaining the advantages of a CISC architecture with improved code density, a 24-bit linear addressing space and an optimized architecture for low-power operations.

The STM8L050J3 MCU includes an integrated debug module with a hardware interface (SWIM) which allows non-intrusive In-Application debugging and ultra-fast Flash programming. It features an embedded data EEPROM and low-power, low-voltage, single-supply program Flash memory.

The device incorporates an extensive range of enhanced I/Os and peripherals, a 12-bit ADC, two comparators, a real-time clock, two 16-bit timers, one 8-bit timer, as well as standard communication interfaces such as an SPI, an I2C interface, and one USART.

The modular design of the peripheral set allows this device to have the same peripherals that can be found in different ST microcontroller families including 32-bit families. This makes any transition to a different family very easy, supported also by the use of a common set of development tools.

STM8L050J3 as all the value line STM8L ultra-low-power products are based on the same architecture with the same memory mapping and a coherent pinout.



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Description STM8L050J3

2.1 Device overview

Table 1. STM8050J3 features and peripheral counts

Features		STM8L050J3
Flash (Kbytes)		8
Data EEPROM (Bytes)		256
RAM (Kbytes)		1
Timers	Basic	1 (8-bit)
Timers	General purpose	2 (16-bit)
	SPI	1
Communicati on interfaces	I2C	1
	USART	1
GPIOs		6
12-bit synchro (number of ch		1 (4)
Comparators (COMP1/COMP2)		2
Others		RTC, window watchdog, independent watchdog, 16-MHz and 32-kHz internal RC, 1- to 16-MHz and 32-kHz external oscillator
CPU frequence	;y	16 MHz
Operating volt	age	1.8 to 3.6 V
Operating tem	perature	−40 to +125 °C
Package		SO8N

STM8L050J3 Description

2.2 Ultra-low-power continuum

STM8L050J3 is part of STM8's ultra-low-power value line on which all the devices are software and feature compatible. Besides the full compatibility within the STM8L family, the devices are part of STMicroelectronics microcontrollers ultra-low-power strategy which also includes the STM8L001xx, STM8L101xx and STM32L15xxx devices. The STM8L and STM32L families allow a continuum of performance, peripherals, system architecture, and features.

They are all based on STMicroelectronics 0.13 µm ultra-low leakage process.

Performance

All the STMicroelectronics ultra-low-power families incorporate highly energy-efficient cores with both Harvard architecture and pipelined execution: advanced STM8 core for STM8L families and ARM® 32-bit Cortex®-M3 core for STM32L family. In addition specific care for the design architecture has been taken to optimize the mA/DMIPS and mA/MHz ratios.

This allows the ultra-low-power performance to range from 5 up to 33.3 DMIPs.

Shared peripherals

The STM8L05xxx, STM8L15xxx and STM32L15xxx devices share identical peripherals which ensure a very easy migration from one family to another:

- Analog peripheral: ADC1 and comparators COMP1/COMP2
- Digital peripherals: RTC and some communication interfaces

Common system strategy

To offer flexibility and optimize performance, the STM8L and STM32L devices use a common architecture:

- Same power supply range from 1.8 to 3.6 V
- Architecture optimized to reach ultra-low consumption both in low-power modes and Run mode
- Fast startup strategy from low-power modes
- Flexible system clock
- Ultra-safe reset: same reset strategy for both STM8L and STM32L including power-on reset, power-down reset, brownout reset and programmable voltage detector.

Features

ST ultra-low-power continuum also lies in feature compatibility:

- More than 11 packages with pin count from 8 to 100 pins and size down to 3 x 3 mm
- Memory density ranging from 2 to 128 Kbytes



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Functional overview STM8L050J3

3 **Functional overview**

Figure 1 presents the basic block diagram which includes all the functional blocks for STM8L050J3.

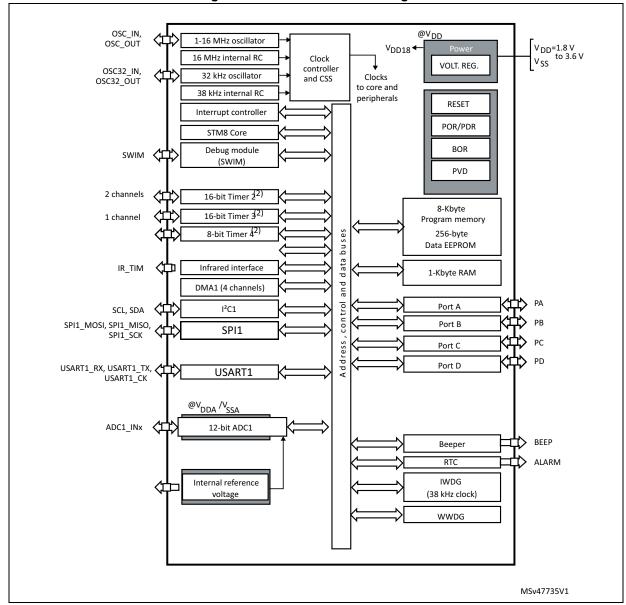


Figure 1. STM8L050J3 block diagram

Legend:

ADC: Analog-to-digital converter BOR: Brownout reset

DMA: Direct memory access I²C: Inter-integrated circuit multimaster interface

IWDG: Independent watchdog
POR/PDR: Power-on reset / power-down reset

RTC: Real-time clock SPI: Serial peripheral interface

SWIM: Single wire interface module USART: Universal synchronous asynchronous receiver transmitter

STM8L050J3 Functional overview

WWDG: Window watchdog

3.1 Low-power modes

mode.

STM8L050J3 as well as all the low density value line STM8L05xxx devices support five low-power modes to achieve the best compromise between low power consumption, short startup time and available wakeup sources:

- Wait mode: The CPU clock is stopped, but selected peripherals keep running. An
 internal or external interrupt or a Reset can be used to exit the microcontroller from
 Wait mode (WFE or WFI mode).
- Low-power run mode: The CPU and the selected peripherals are running. Execution is done from RAM with a low speed oscillator (LSI or LSE). Flash memory and data EEPROM are stopped and the voltage regulator is configured in ultra-low-power mode. The microcontroller enters Low-power run mode by software and can exit from this mode by software or by a reset.
 All interrupts must be masked. They cannot be used to exit the microcontroller from this
- Low-power wait mode: This mode is entered when executing a Wait for event in Low-power run mode. It is similar to Low-power run mode except that the CPU clock is stopped. The wakeup from this mode is triggered by a Reset or by an internal or external event (peripheral event generated by the timers, serial interfaces, DMA controller (DMA1), comparators and I/O ports). When the wakeup is triggered by an event, the system goes back to Low-power run mode.
 All interrupts must be masked. They cannot be used to exit the microcontroller from this mode.
- Active-halt mode: CPU and peripheral clocks are stopped, except RTC. The wakeup can be triggered by RTC interrupts, external interrupts or reset.
- Halt mode: CPU and peripheral clocks are stopped, the device remains powered on. The RAM content is preserved. The wakeup is triggered by an external interrupt or reset. A few peripherals have also a wakeup from Halt capability. Switching off the internal reference voltage reduces power consumption. Through software configuration it is also possible to wake up the device without waiting for the internal reference voltage wakeup time to have a fast wakeup time of 5 µs.



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Functional overview STM8L050J3

3.2 Central processing unit STM8

The central processing unit represents the core of the microcontroller; it executes code and controls the peripherals.

3.2.1 Advanced STM8 Core

The 8-bit STM8 core is designed for code efficiency and performance with an Harvard architecture and a 3-stage pipeline.

It contains 6 internal registers which are directly addressable in each execution context, 20 addressing modes including indexed indirect and relative addressing, and 80 instructions.

Architecture and registers

- Harvard architecture
- 3-stage pipeline
- 32-bit wide program memory bus single cycle fetching most instructions
- X and Y 16-bit index registers enabling indexed addressing modes with or without offset and read-modify-write type data manipulations
- 8-bit accumulator
- 24-bit program counter 16-Mbyte linear memory space
- 16-bit stack pointer access to a 64-Kbyte level stack
- 8-bit condition code register 7 condition flags for the result of the last instruction

Addressing

- 20 addressing modes
- Indexed indirect addressing mode for lookup tables located anywhere in the address space
- Stack pointer relative addressing mode for local variables and parameter passing

Instruction set

- 80 instructions with 2-byte average instruction size
- Standard data movement and logic/arithmetic functions
- 8-bit by 8-bit multiplication
- 16-bit by 8-bit and 16-bit by 16-bit division
- Bit manipulation
- Data transfer between stack and accumulator (push/pop) with direct stack access
- Data transfer using the X and Y registers or direct memory-to-memory transfers

3.2.2 Interrupt controller

STM8L050J3 and all the low density value line STM8L05xxx feature a nested vectored interrupt controller:

- Nested interrupts with 3 software priority levels
- 32 interrupt vectors with hardware priority
- Up to 6 external interrupt sources on 6 vectors
- Trap and reset interrupts



STM8L050J3 Functional overview

3.3 Reset and supply management

The power supplies requirements must be defined in order to have a correct microcontroller operation. The reset and supply management controls the microcontroller operation under defined conditions.

3.3.1 Power supply scheme

The device requires a 1.8 V to 3.6 V operating supply voltage (V_{DD}). The external power supply pins must be connected as follows:

- V_{SS1} ; V_{DD1} = 1.8 to 3.6 V: external power supply for I/Os and for the internal regulator. Provided externally through V_{DD1} pins, the corresponding ground pin is V_{SS1} .
- V_{SSA} ; V_{DDA} = 1.8 to 3.6 V: external power supplies for analog peripherals. V_{DDA} and V_{SSA} is internally bonded to V_{DD1} and V_{SS1} , respectively.
- V_{REF+}, V_{REF-} (for ADC1): external reference voltage for ADC1 internally bonded to V_{SS1} / V_{DD1} and externally through V_{REF+} and V_{REF-} pin.

3.3.2 Power supply supervisor

The device has an integrated ZEROPOWER power-on reset (POR)/power-down reset (PDR), coupled with a brownout reset (BOR) circuitry. When the microcontroller operates between 1.8 and 3.6 V, BOR is always active and ensures proper operation starting from 1.8 V. After the 1.8 V BOR threshold is reached, the option byte loading process starts, either to confirm or modify default thresholds, or to disable BOR permanently.

Five BOR thresholds are available through option bytes, starting from 1.8 V to 3 V. To reduce the power consumption in Halt mode, it is possible to automatically switch off the internal reference voltage (and consequently the BOR) in Halt mode. The device remains in reset state when V_{DD} is below a specified threshold, $V_{POR/PDR}$ or V_{BOR} , without the need for any external reset circuit.

The device features an embedded programmable voltage detector (PVD) that monitors the V_{DD}/V_{DDA} power supply and compares it to the V_{PVD} threshold. This PVD offers 7 different levels between 1.85 V and 3.05 V, chosen by software, with a step around 200 mV. An interrupt can be generated when V_{DD}/V_{DDA} drops below the V_{PVD} threshold and/or when V_{DD}/V_{DDA} is higher than the V_{PVD} threshold. The interrupt service routine can then generate a warning message and/or put the MCU into a safe state. The PVD is enabled by software.

3.3.3 Voltage regulator

STM8L050J3 as all the low density value line STM8L05xxx embeds an internal voltage regulator for generating the 1.8 V power supply for the core and peripherals.

This regulator has two different modes:

- Main voltage regulator mode (MVR) for Run, Wait for interrupt (WFI) and Wait for event (WFE) modes.
- Low-power voltage regulator mode (LPVR) for Halt, Active-halt, Low-power run and Low-power wait modes.

When entering Halt or Active-halt modes, the system automatically switches from the MVR to the LPVR in order to reduce current consumption.



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Functional overview STM8L050J3

3.4 Clock management

The clock controller distributes the system clock (SYSCLK) coming from different oscillators to the core and the peripherals. It also manages clock gating for low-power modes and ensures clock robustness.

Features

- Clock prescaler: to get the best compromise between speed and current consumption the clock frequency to the CPU and peripherals can be adjusted by a programmable prescaler.
- **Safe clock switching:** Clock sources can be changed safely on the fly in run mode through a configuration register.
- **Clock management:** To reduce power consumption, the clock controller can stop the clock to the core, individual peripherals or memory.
- System clock sources: four different clock sources can be used to drive the system clock:
 - 1-16 MHz High speed external crystal (HSE)
 - 16 MHz High speed internal RC oscillator (HSI)
 - 32.768 Low speed external crystal (LSE)
 - 38 kHz Low speed internal RC (LSI)
- RTC clock sources: the above four sources can be chosen to clock the RTC whatever the system clock.
- **Startup clock:** After reset, the microcontroller restarts by default with an internal 2 MHz clock (HSI/8). The prescaler ratio and clock source can be changed by the application program as soon as the code execution starts.
- Clock security system (CSS): This feature can be enabled by software. If a HSE clock failure occurs, it is automatically switched to HSI.
- Configurable main clock output (CCO): This outputs an external clock for use by the application.



STM8L050J3 Functional overview

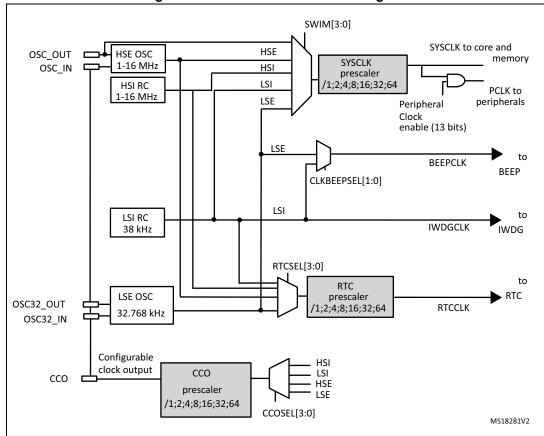


Figure 2. STM8L050J3 clock tree diagram

- The HSE clock source can be either an external crystal/ceramic resonator or an external source (HSE bypass). Refer to Section HSE clock in the STM8L050J3, STM8L051F3, STM8L052C6, STM8L052R8 MCUs and STM8L151/L152, STM8L162, STM8AL31, STM8AL3L lines reference manual (RM0031).
- The LSE clock source can be either an external crystal/ceramic resonator or a external source (LSE bypass). Refer to Section LSE clock in the STM8L050J3, STM8L051F3, STM8L052C6, STM8L052R8 MCUs and STM8L151/L152, STM8L162, STM8AL31, STM8AL3L lines reference manual (RM0031).

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Functional overview STM8L050J3

3.5 Low power real-time clock

The real-time clock (RTC) is an independent binary coded decimal (BCD) timer/counter.

Six byte locations contain the second, minute, hour (12/24 hour), week day, date, month, year, in BCD (binary coded decimal) format. Correction for 28, 29 (leap year), 30, and 31 day months are made automatically.

It provides a programmable alarm and programmable periodic interrupts with wakeup from Halt capability.

- Periodic wakeup time using the 32.768 kHz LSE with the lowest resolution (of 61 μ s) is from min. 122 μ s to max. 3.9 s. With a different resolution, the wakeup time can reach 36 hours
- Periodic alarms based on the calendar can also be generated from every second to every year

3.6 Memories

STM8L050J3 as all the low density value line STM8L05xxx devices have the following main features:

- Up to 1 Kbyte of RAM
- The non-volatile memory is divided into three arrays:
 - 8 Kbytes of low-density embedded Flash program memory
 - 256 bytes of Data EEPROM
 - Option bytes

The EEPROM embeds the error correction code (ECC) feature.

The option byte protects part of the Flash program memory from write and readout piracy.

Recommendation for the device's programming

The device's 8 Kbytes program memory is not empty on virgin devices; there is code loop implemented on the reset vector. It is recommended to keep valid code loop in the device to avoid the program execution from an invalid memory address (which would be any memory address out of 8 Kbytes program memory space).

If the device's program memory is empty (0x00 content), it displays the behavior described below:

- After the power on, the "empty" code is executed (0x0000 opcodes = instructions: NEG (0x00, SP)) until the device reaches the end of the 8 Kbytes program memory (the end address = 0x9FFF).
 - It takes around 4 milliseconds to reach the end of the 8 Kbytes memory space @2 MHz HSI clock.
- Once the device reaches the end of the 8 Kbytes program memory, the program continues and code from a non-existing memory is fetched and executed.

The reading of non-existing memory is a random content which can lead to the execution of invalid instructions.

The execution of invalid instructions generates a software reset and the program starts again. A reset can be generated every 4 milliseconds or more.



STM8L050J3 Functional overview

Only the "connect on-the-fly" method can be used to program the device through the SWIM interface. The "connect under-reset" method cannot be used because the NRST pin is not available on this device.

The "connect on-the-fly" mode can be used while the device is executing code, but if there is a device reset (by software reset) during the SWIM connection, this connection is aborted and it must be performed again from the debug tool. Note that the software reset occurrence can be of every 4 milliseconds, making it difficult to successfully connect to the device's debug tool (there is practically only one successful connection trial for every 10 attempts). Once that a successful connection is reached, the device can be programmed with a valid firmware without problems; therefore it is recommended that device is never erased and that it always contains a valid code loop.

3.7 DMA

A 4-channel direct memory access controller (DMA1) offers a memory-to-memory and peripherals-from/to-memory transfer capability. The 4 channels are shared between the following IPs with DMA capability: ADC1, I2C1, SPI1, USART1, and the three timers.

3.8 Analog-to-digital converter

- 12-bit analog-to-digital converter (ADC1) with 4 channels (no fast channel) and internal reference voltage
- Conversion time down to 1 μs with f_{SYSCLK}= 16 MHz
- Programmable resolution
- Programmable sampling time
- Single and continuous mode of conversion
- Scan capability: automatic conversion performed on a selected group of analog inputs
- Analog watchdog
- Triggered by timer

Note: ADC1 can be served by DMA1.

3.9 Ultra-low-power comparators

The low-density STM8L050J3xx embed two comparators (COMP1 and COMP2) sharing the same current bias and voltage reference. The voltage reference can be internal or external (coming from an I/O). Each comparator has a different threshold type:

- One comparator with fixed threshold (COMP1)
- One comparator rail to rail with fast or slow mode (COMP2). The threshold can be of the following:
 - External I/O
 - Internal reference voltage or internal reference voltage sub multiple (1/4, 1/2, 3/4)

The two comparators can be used together to offer a window function. They can wake up from Halt mode.



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3.10 System configuration controller and routing interface

The system configuration controller provides the capability to remap some alternate functions on different I/O ports. TIM4 and ADC1 DMA channels can also be remapped.

The highly flexible routing interface controls the routing of internal analog signals to ADC1 and the internal reference voltage V_{REFINT} .

3.11 Timers

STM8L050J3 contains two 16-bit general purpose timers (TIM2 and TIM3) and one 8-bit basic timer (TIM4).

All the timers can be served by DMA1.

Table 2 compares the features of the advanced control, general-purpose and basic timers.

Timer	Counter resolution	Counter type	Prescaler factor	DMA1 request generation	Capture/compare channels	Complementary outputs
TIM2	16-bit	up/down	Any power of 2		2	
TIM3	10-bit	up/down	from 1 to 128	Yes	1	None
TIM4	8-bit	up	Any power of 2 from 1 to 32768	- 55	0	113116

Table 2. Timer feature comparison

3.11.1 16-bit general purpose timers (TIM2, TIM3)

- 16-bit autoreload (AR) up/down-counter
- 7-bit prescaler adjustable to fixed power of 2 ratios (1...128)
- Individually configurable capture/compare channels
- PWM mode
- Interrupt capability on various events (capture, compare, overflow, break, trigger)
- Synchronization with other timers or external signals (external clock, reset, trigger and enable)

3.11.2 8-bit basic timer (TIM4)

The 8-bit timer consists of an 8-bit up auto-reload counter driven by a programmable prescaler. It can be used for timebase generation with interrupt generation on timer overflow.

3.12 Watchdog timers

The watchdog system is based on two independent timers providing maximum security to the applications.



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3.12.1 Window watchdog timer

The window watchdog (WWDG) is used to detect the occurrence of a software fault, usually generated by external interferences or by unexpected logical conditions, which cause the application program to abandon its normal sequence.

3.12.2 Independent watchdog timer

The independent watchdog peripheral (IWDG) can be used to resolve processor malfunctions due to hardware or software failures.

It is clocked by the internal LSI RC clock source, and thus stays active even in case of a CPU clock failure.

3.13 Beeper

The beeper function outputs a signal on the BEEP pin for sound generation. The signal is in the range of 1, 2 or 4 kHz.

3.14 Communication interfaces

This section describes the three communication interfaces of STM8L050J3: SPI, I2C and USART.

3.14.1 SPI

The serial peripheral interfaces (SPI1) provide half/ full duplex synchronous serial communication with external devices.

- Maximum speed: 8 Mbit/s (f_{SYSCLK}/2) both for master and slave
- Full duplex synchronous transfers
- Simplex synchronous transfers on 2 lines with a possible bidirectional data line
- Master or slave operation selectable by hardware or software
- Hardware CRC calculation

Note: SPI1 can be served by the DMA1 Controller.

Slave selection pin (NSS) is supported only in a slave receive-only mode.

3.14.2 I2C

The I2C bus interface (I2C1) provides multi-master capability, and controls all I2C busspecific sequencing, protocol, arbitration and timing.

- Master, slave and multi-master capability
- Standard mode up to 100 kHz and fast speed modes up to 400 kHz
- 7-bit and 10-bit addressing modes
- SMBus 2.0 and PMBus support
- Hardware CRC calculation

Note: I2C1 can be served by the DMA1 Controller.



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3.14.3 USART

The USART interface (USART1) allows full duplex, asynchronous communications with external devices requiring an industry standard NRZ asynchronous serial data format. It offers a very wide range of baud rates.

- 1 Mbit/s full duplex SCI
- SPI emulation
- High precision baud rate generator
- Smartcard emulation
- IrDA SIR encoder decoder
- Single wire half duplex mode

Note: USART1 can be served by the DMA1 Controller.

3.15 Infrared (IR) interface

The low density STM8L05xxx devices contain an infrared interface which can be used with an IR LED for remote control functions. Two timer output compare channels are used to generate the infrared remote control signals.

3.16 Development support

Development tools

Development tools for the STM8 microcontrollers include:

- The STice emulation system offering tracing and code profiling
- The STVD high-level language debugger including C compiler, assembler and integrated development environment
- The STVP Flash programming software

The STM8 also comes with starter kits, evaluation boards and low-cost in-circuit debugging/programming tools.

Single wire data interface (SWIM) and debug module

The debug module with its single wire data interface (SWIM) permits non-intrusive real-time in-circuit debugging and fast memory programming.

The Single wire interface is used for direct access to the debugging module and memory programming. The interface can be activated in all device operation modes.

The non-intrusive debugging module features a performance close to a full-featured emulator. Beside memory and peripherals, CPU operation can also be monitored in real-time by means of shadow registers.

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Recommendations for SWIM pin (pin#1) sharing

If the SWIM pin should be used with the I/O pin functionality, it is recommended to add a \sim 5 seconds delay in the firmware before changing the functionality on the pin with SWIM functions. This action allows the user to set the device into SWIM mode after the device power on and to be able to reprogram the device. If the pin with SWIM functionality is set to I/O mode immediately after the device reset, the device is unable to connect through the SWIM interface and it will be locked forever (if the NRST pin is not available on the package). This initial delay can be removed in the final (locked) code.

If the initial delay is not acceptable for the application there is the option that the firmware reenables the SWIM pin functionality under specific conditions such as during firmware startup or during application run. Once that this procedure is done, the SWIM interface can be used for device debug/programming.

Bootloader

STM8L050J3 features a built-in bootloader(which supports USART interface on pins 8 and 1: PC5 = TxD, PC6 RxD). See *STM8 bootloader* user manual (UM0560).

The bootloader is used to download application software into the device memories, including RAM, program and data memory, using standard serial interfaces. It is a complementary solution to programming via the SWIM debugging interface.



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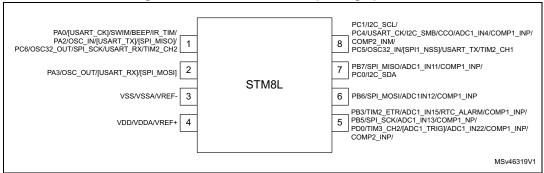
Downloaded from **Arrow.com**.

Pin description STM8L050J3

4 Pin description

This section describes the device's pin functions (see *Table 4*) and package's pinout (see *Figure 3*).

Figure 3. STM8L050J3 SO8N package pinout



 [] Alternative function option. If the same alternate function is shown twice, it indicates an exclusive choice and not a duplication of the function.

Table 3. Legend/abbreviation for Table 4

Туре	I= input, O =	I= input, O = output, S = power supply					
Level	Output HS = high sink/source (20 mA)						
Level	Input FT - five volt tolerant						
Port and control	Input float = floating, wpu = weak pull-up						
configuration	Output	Output T = true open drain, OD = open drain, PP = push pull					
Reset state Bold X (pin state after reset release). Unless otherwise specified, the pin state is the same during the reset (i.e. "under reset") and after internal reset release (i.e. at reset state).							



STM8L050J3 Pin description

Table 4. STM8L050J3 pin description

pin n°			Input			ıt (Output		cription		
N8OS	Pin name	Type	I/O level	floating	ndw	Ext. interrupt	High sink/source	OD	ВР	Main function (after reset)	Default alternate function	
	PA0 ⁽¹⁾ /[USART_CK] ⁽²⁾ / SWIM/BEEP/IR_TIM ⁽³⁾	I/O	-	X	X (1)	Χ	HS (3)	X	X	Port A0	[USART1 synchronous clock] ⁽²⁾ / SWIM input and output / Beep output / Infrared Timer output	
1	PA2/OSC_IN/[USART_TX] ⁽²⁾ / [SPI_MISO] ^{(2) (4)}	I/O	-	X (1)	X	Х	HS	Х	Х	Port A2	HSE oscillator input / [USART transmit] / [SPI master in- slave out]	
	PC6/OSC32_OUT/[SPI_SCK] ⁽²⁾ /[USART_RX]/TIM2_CH2	I/O	-	X (1)	X	Х	HS	X	Х	Port C6	LSE oscillator output / [SPI clock] / [USART receive]/ Timer 2 -channel 2	
2	PA3/OSC_OUT/[USART_RX] ⁽²⁾ /[SPI_MOSI] ⁽²⁾	I/O	-	X	Х	Х	HS	Х	Х	Port A3	HSE oscillator output / [USART receive]/ [SPI master out/slave in]	
3	V _{SS} / V _{REF-} / V _{SSA}	-	-	1	ı	1	-	-	-	Ground voltage / ADC1 negative voltage reference / Analog ground voltage		
4	V _{DD} / V _{DDA} / V _{REF+}	s	-	-	-	-	-	-	-		upply voltage /Analog supply voltage ositive voltage reference	
	PB3/TIM2_ETR/ ADC1_IN15/RTC_ALARM/COM P1_INP	I/O	-	x	Х	Х	HS	Х	Х	Port B3	Timer 2 - external trigger / ADC1_IN15 / RTC_ALARM/ Comparator1 positive input	
5	PB5/SPI_SCK/ADC1_IN13/CO MP1_INP	I/O	-	X	Х	Х	HS	Х	Х	Port B5	[SPI clock] / ADC1_IN13/ Comparator1 positive input	
	PD0/TIM3_CH2/[ADC1_TRIG] ⁽²)/ADC1_IN22/COMP1_INP/CO MP2_INP	I/O	-	x	х	Х	HS	Х	Х	Port D0	Timer 3 - channel 2 / [ADC1_Trigger] / ADC1_IN22/ Comparator1 positive input/ Comparator2 positive input	
6	PB6/SPI_MOSI/ ADC1_IN12/COMP1_INP	I/O	-	x	Х	Х	HS	Х	Х	Port B6	SPI master out/ slave in / ADC1_IN12/ Comparator1 positive input	
7	PB7/SPI_MISO/ADC1_IN11/CO MP1_INP	I/O	-	x	Х	Х	HS	Х	Х	Port B7	SPI1 master in- slave out/ ADC1_IN11/ Comparator1 positive input	
	PC0/I2C_SDA	I/O	-	X	ı	X	-	T ⁽⁵⁾	-	Port C0	I2C data	



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Pin description STM8L050J3

pin Input Output n° Main function (after reset) sink/source eve interrupt **Default alternate function** Pin name floating 9 ndw Ь EX F High Port T⁽⁵⁾ PC1/I2C_SCL I/O X Χ I2C clock C1 USART synchronous clock / PC4/USART_CK]/ I2C1 SMB / Configurable clock **Port** I2C_SMB/CCO/ADC1 IN4/CO I/O HS Χ output / ADC1 IN4/ Comparator1 X Χ Χ Х C4 MP1 INP/COMP2 INM positive input/ Comparator2 negative input LSE oscillator input / [SPI PC5/OSC32 IN /[SPI NSSI(2)/ Port I/O X Χ Х Χ HS Χ master/slave select] / [USART [USART_TX]/TIM2 CH1 C5 transmit]/Timer 2 -channel 1

Table 4. STM8L050J3 pin description (continued)

- 1. The PA0 pin is in input pull-up during the reset phase and after reset release. The default PA0 influences all the GPIOs connected in parallel on pin number 1 (PA2, PC6).
- 2. [] Alternate function remapping option (if the same alternate function is shown twice, it indicates an exclusive choice not a duplication of the function).
- 3. High Sink LED driver capability available on PA0.
- 4. The SPI_MISO signal on PA2 (pin1) cannot be used in application because it is shared with the SPI_SCK signal on the same pin.
- 5. In the open-drain output column, 'T' defines a true open-drain I/O (P-buffer and protection diode to VDD are not implemented). Although PC0/PC1 itself is a true open drain GPIO with its respective circuitry and characteristics, the maximum V_{IN} of the pin number 7 and pin number 8 is limited by the standard GPIO (PB7 or PC4/PC5) which is also bonded to the same pin number.

Note: 1 The slope control of all GPIO pins, except true open drain pins, can be programmed. By default, the slope control is limited to 2 MHz.

- 2 The PA1, PB0, PB1, PB2 and PB4 should be configured after device reset by user software into the output push-pull mode with output low-state to reduce the device's consumption and to improve its EMC immunity. The GPIOs mentioned above are not connected to pins, and they are in input-floating mode after a device reset. To configure PA1 pin in output push-pull mode refer to Section "Configuring NRST/PA1 pin as general purpose output" in the STM8L050J3, STM8L051F3, STM8L052C6, STM8L052R8 MCUs and STM8L151/L152, STM8L162, STM8AL31, STM8AL3L lines reference manual (RM0031).
- As several pins provide a connection to multiple GPIOs, the mode selection for any of those GPIOs impacts all the other GPIOs connected to the same pin. The user is responsible for the proper setting of the GPIO modes in order to avoid conflicts between GPIOs bonded to the same pin (including their alternate functions). For example, pull-up enabled on PA0 is also seen on PA2 and PC6. Push-pull configuration of PB3 is also seen on PB5 and PD0, etc.



STM8L050J3 Pin description

4.1 System configuration options

As shown in *Table 4: STM8L050J3 pin description*, some functions can be remapped on different I/O ports by programming one of the two remapping registers described in the "Routing interface (RI) and system configuration controller" section in the *STM8L050J3*, *STM8L051F3*, *STM8L052C6*, *STM8L052R8 MCUs and STM8L151/L152*, *STM8L162*, *STM8AL31*, *STM8AL3L lines* reference manual (RM0031).



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Memory and register map 5

The following sections describe the mapping of the device's memory and peripherals.

Memory mapping 5.1

The memory map is shown in Figure 4.

Figure 4. STML050J3 memory map 0x00 5000 GPIO ports 0x00 501I Reserved 0x00 5050 0x00 5055 0x000000Reserved 0x00 5070 RAM (Up to 1 Kbyte) DMA1 0x00 509E including SYSCFG 0x00 50A0 Stack (512 bytes) ITC-EXT1 0x00 03FF 0x00 50A6 0x00 0400 0x00 50A Reserved ITC-EXT1 0x001FFF 0x00 50A 0x00 1000 0x00 50B0 Data EEPROM (256 Bytes) 0x00 10FF Reserved 0x001100 0x00 50C0 CLK Reserved 0x00 50D Reserved 0x00 47FF 0x00 50D WWDG 0x004800 0x00 50D Option bytes 0x00 487F 0x00 50E 0x004880 0x00 50E3 Reserved 0x00 4FFF 0x00 5000 0x00 50F0 0x00 50F GPIO and peripheral registers Reserved 0x00 5040 0x00 5457 0x00 5191 0x005458 0x00 5200 Reserved SPI1 0x00 5208 0x00 5FFF 0x00 5210 0x006000 Boot ROM 0x00 521 (2 Kbytes) 0x00 67FF 0x00 523 USART1 0x006800 0x00 523E Reserved 0x00 525 TIM2 0x00 7EFF 0x00 526 0x00 7F00 Reserved 0x00 528 CPU/SWIM/Debug/ITC 0x00 529 Registers 0x00 7FFF 0x00 52E0 0x008000 0x00 52EA Reset and interrupt vectors 0x00 80FF 0x00 52FF IRTIM 0x008100 0x00 5317 Reserved Low density 0x00 534 ADC1 Flash program memory 0x00 53C (8 Kbytes) 0x00 5430 0x00 9FFF 0x00 544 0x00 5450 RI MS18274V3

1. Table 5 lists the boundary addresses for each memory size. The top of the stack is at the RAM end

address.

2. Refer to *Table 7* for an overview of hardware register mapping, to *Table 6* for details on I/O port hardware registers, and to *Table 8* for information on CPU/SWIM/debug module controller registers.

Table 5. Flash and RAM boundary addresses

Memory area	Size	Start address	End address	
RAM	1 Kbyte	0x00 0000	0x00 03FF	
Flash program memory	8 Kbytes	0x00 8000	0x00 9FFF	

5.2 Register map

Table 6. I/O port hardware register map

Address	Block	Register label	Register name	Reset status
0x00 5000		PA_ODR	Port A data output latch register	0x00
0x00 5001		PA_IDR	Port A input pin value register	0xXX
0x00 5002	Port A	PA_DDR	Port A data direction register	0x00
0x00 5003		PA_CR1	Port A control register 1	0x01
0x00 5004	-	PA_CR2	Port A control register 2	0x00
0x00 5005		PB_ODR	Port B data output latch register	0x00
0x00 5006		PB_IDR	Port B input pin value register	0xXX
0x00 5007	Port B	PB_DDR	Port B data direction register	0x00
0x00 5008		PB_CR1	Port B control register 1	0x00
0x00 5009		PB_CR2	Port B control register 2	0x00
0x00 500A		PC_ODR	Port C data output latch register	0x00
0x00 500B		PB_IDR	Port C input pin value register	0xXX
0x00 500C	Port C	PC_DDR	Port C data direction register	0x00
0x00 500D		PC_CR1	Port C control register 1	0x00
0x00 500E		PC_CR2	Port C control register 2	0x00
0x00 500F		PD_ODR	Port D data output latch register	0x00
0x00 5010		PD_IDR	Port D input pin value register	0xXX
0x00 5011	Port D	PD_DDR	Port D data direction register	0x00
0x00 5012		PD_CR1	Port D control register 1	0x00
0x00 5013		PD_CR2	Port D control register 2	0x00
0x00 5014 to 0x00 501D		F	Reserved area (0 bytes)	



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Table 7. General hardware register map

Address	Block	Register label	Register name	Reset status		
0x00 502E to 0x00 5049		Reserved area (44 bytes)				
0x00 5050		FLASH_CR1	Flash control register 1	0x00		
0x00 5051		FLASH_CR2	Flash control register 2	0x00		
0x00 5052	Flash	FLASH_PUKR	Flash program memory unprotection key register	0x00		
0x00 5053		FLASH_DUKR	Data EEPROM unprotection key register	0x00		
0x00 5054		FLASH_IAPSR	Flash in-application programming status register	0x00		
0x00 5055 to 0x00 506F		R	leserved area (27 bytes)			
0x00 5070		DMA1_GCSR	DMA1 global configuration & status register	0xFC		
0x00 5071		DMA1_GIR1	DMA1 global interrupt register 1	0x00		
0x00 5072 to 0x00 5074		Reserved area (3 bytes)				
0x00 5075		DMA1_C0CR	DMA1 channel 0 configuration register	0x00		
0x00 5076		DMA1_C0SPR	DMA1 channel 0 status & priority register	0x00		
0x00 5077		DMA1_C0NDTR	DMA1 number of data to transfer register (channel 0)	0x00		
0x00 5078	DMA1	DMA1_C0PARH	DMA1 peripheral address high register (channel 0)	0x52		
0x00 5079		DMA1_C0PARL	DMA1 peripheral address low register (channel 0)	0x00		
0x00 507A			Reserved area (1 byte)			
0x00 507B		DMA1_C0M0ARH	DMA1 memory 0 address high register (channel 0)	0x00		
0x00 507C		DMA1_C0M0ARL	DMA1 memory 0 address low register (channel 0)	0x00		

Table 7. General hardware register map (continued)

Address	Block	Register label	Register name	Reset status
0x00 507D to 0x00 507E		Reserved area (2 bytes)		
0x00 507F		DMA1_C1CR	DMA1 channel 1 configuration register	0x00
0x00 5080		DMA1_C1SPR	DMA1 channel 1 status & priority register	0x00
0x00 5081		DMA1_C1NDTR	DMA1 number of data to transfer register (channel 1)	0x00
0x00 5082		DMA1_C1PARH	DMA1 peripheral address high register (channel 1)	0x52
0x00 5083		DMA1_C1PARL	DMA1 peripheral address low register (channel 1)	0x00
0x00 5084			Reserved area (1 byte)	·
0x00 5085		DMA1_C1M0ARH	DMA1 memory 0 address high register (channel 1)	0x00
0x00 5086		DMA1_C1M0ARL	DMA1 memory 0 address low register (channel 1)	0x00
0x00 5087 0x00 5088			Reserved area (2 bytes)	
0x00 5089		DMA1_C2CR	DMA1 channel 2 configuration register	0x00
0x00 508A		DMA1_C2SPR	DMA1 channel 2 status & priority register	0x00
0x00 508B	DMA1	DMA1_C2NDTR	DMA1 number of data to transfer register (channel 2)	0x00
0x00 508C		DMA1_C2PARH	DMA1 peripheral address high register (channel 2)	0x52
0x00 508D		DMA1_C2PARL	DMA1 peripheral address low register (channel 2)	0x00
0x00 508E			Reserved area (1 byte)	
0x00 508F		DMA1_C2M0ARH	DMA1 memory 0 address high register (channel 2)	0x00
0x00 5090		DMA1_C2M0ARL	DMA1 memory 0 address low register (channel 2)	0x00
0x00 5091 0x00 5092			Reserved area (2 bytes)	1
0x00 5093		DMA1_C3CR	DMA1 channel 3 configuration register	0x00
0x00 5094		DMA1_C3SPR	DMA1 channel 3 status & priority register	0x00
0x00 5095		DMA1_C3NDTR	DMA1 number of data to transfer register (channel 3)	0x00
0x00 5096		DMA1_C3PARH_ C3M1ARH	DMA1 peripheral address high register (channel 3)	0x40
0x00 5097		DMA1_C3PARL_ C3M1ARL	DMA1 peripheral address low register (channel 3)	0x00



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Table 7. General hardware register map (continued)

Address	Block	Register label	Register name	Reset status	
0x00 5098		DMA_C3M0EAR	DMA channel 3 memory 0 extended address register	0x00	
0x00 5099	DMA1	DMA1_C3M0ARH	DMA1 memory 0 address high register (channel 3)	0x00	
0x00 509A	DIMAT	DMA1_C3M0ARL	DMA1 memory 0 address low register (channel 3)	0x00	
0x00 509B to 0x00 509C			Reserved area (3 bytes)		
0x00 509D		SYSCFG_RMPCR3	Remapping register 3	0x00	
0x00 509E	SYSCFG	SYSCFG_RMPCR1	Remapping register 1	0x2C	
0x00 509F		SYSCFG_RMPCR2	Remapping register 2	0x00	
0x00 50A0		EXTI_CR1	External interrupt control register 1	0x00	
0x00 50A1		EXTI_CR2	External interrupt control register 2	0x00	
0x00 50A2	ITO EVT	EXTI_CR3	External interrupt control register 3	0x00	
0x00 50A3	ITC - EXTI	EXTI_SR1	External interrupt status register 1	0x00	
0x00 50A4		EXTI_SR2	External interrupt status register 2	0x00	
0x00 50A5		EXTI_CONF1	External interrupt port select register 1	0x00	
0x00 50A6		WFE_CR1	WFE control register 1	0x00	
0x00 50A7	\A/FF	WFE_CR2	WFE control register 2	0x00	
0x00 50A8	WFE	WFE_CR3	WFE control register 3	0x00	
0x00 50A9		WFE_CR4	WFE control register 4	0x00	
0x00 50AA	ITC - EXTI	EXTI_CR4	External interrupt control register 4	0x00	
0x00 50AB		EXTI_CONF2	External interrupt port select register 2	0x00	
0x00 50A9 to 0x00 50AF		Reserved area (7 bytes)			
0x00 50B0	RST	RST_CR	Reset control register	0x00	
0x00 50B1	KOI	RST_SR	Reset status register	0x01	
0x00 50B2	DWD	PWR_CSR1	Power control and status register 1	0x00	
0x00 50B3	PWR	PWR_CSR2	Power control and status register 2	0x00	
0x00 50B4 to 0x00 50BF	Reserved area (12 bytes)				
0x00 50C0	CLK	CLK_CKDIVR	CLK Clock master divider register	0x03	
0x00 50C1		CLK_CRTCR	CLK Clock RTC register	0x00 ⁽¹⁾	
0x00 50C2		CLK_ICKCR	CLK Internal clock control register	0x11	
0x00 50C3		CLK_PCKENR1	CLK Peripheral clock gating register 1	0x00	



Table 7. General hardware register map (continued)

0x00 50C4 CLK_PCKENR2 CLK Peripheral clock gating register 2 0x00 0x00 50C6 CLK_CCOR CLK Configurable clock control register 0x00 0x00 50C7 CLK_ECKCR CLK External clock control register 0x00 0x00 50C8 CLK_SCSR CLK System clock status register 0x01 0x00 50C8 CLK_SWCR CLK Clock switch control register 0x00 0x00 50CB CLK_CSSR CLK Clock switch control register 0x00 0x00 50CB CLK_CSSR CLK Clock security system register 0x00 0x00 50CD CLK_HSICALR CLK HSI calibration register 0x00 0x00 50CE CLK_HSITRIMR CLK HSI calibration trimming register 0x00 0x00 50CE CLK_HSILNILCKR CLK HSI unlock register 0x00 0x00 50CF CLK_PCKENR3 CLK Peripheral clock gating register 3 0x00 0x00 50D1 0x00 50D2 CLK_PCKENR3 CLK Peripheral clock gating register 3 0x00 0x00 50D3 WWDG WWDG_WR WWDG we prescale register 3 0x00 0x00 50D4 WWDG_WR WWDG we	Address	Block	Register label	Register name	Reset status		
0x00 50C6 0x00 50C7 CLK_ECKCR CLK External clock control register 0x00 0x00 50C7 0x00 50C8 CLK_SCSR CLK System clock status register 0x01 0x00 50C9 CLK_SWR CLK System clock switch register 0x00 0x00 50C9 CLK_SWCR CLK Clock switch control register 0x00 0x00 50C0 CLK_CBEEPR CLK Clock security system register 0x00 0x00 50CD CLK_HSICALR CLK HSI calibration register 0x00 0x00 50CE CLK_HSITRIMR CLK HSI clock calibration trimming register 0x00 0x00 50CE CLK_HSIUNLCKR CLK HSI unlock register 0x00 0x00 50DD CLK_PCKENR3 CLK Peripheral clock gating register 0x00 0x00 50D1 to Reserved area (2 bytes) 0x7F 0x00 50D2 WWDG_WR WWDG control register 0x7F 0x00 50D5 to WWDG_WR WWDG writer register 0x01 0x00 50D6 to WWDG_WR WWDG writer register 0x01 0x00 50D6 to WDG_PR IWDG prescaler register 0x01 <td< td=""><td>0x00 50C4</td><td></td><td>CLK_PCKENR2</td><td>CLK Peripheral clock gating register 2</td><td>0x00</td></td<>	0x00 50C4		CLK_PCKENR2	CLK Peripheral clock gating register 2	0x00		
0x00 50C7 CLK_SCSR CLK System clock status register 0x01 0x00 50C8 CLK_SWR CLK System clock switch register 0x01 0x00 50C9 CLK_SWCR CLK Clock switch control register 0x00 0x00 50CB CLK_CSSR CLK Clock security system register 0x00 0x00 50CC CLK_HSICALR CLK HSI calibration register 0x00 0x00 50CE CLK_HSIUNLCKR CLK HSI unlock register 0x00 0x00 50CE CLK_HSIUNLCKR CLK HSI unlock register 0x00 0x00 50CE CLK_REGCSR CLK Main regulator control status register 0x00 0x00 50D0 CLK_PCKENR3 CLK Peripheral clock gating register 0x00 0x00 50D1 Reserved area (2 bytes) 0x7F 0x00 50D2 WWDG_WR WWDG control register 0x7F 0x00 50D4 WWDG_WR WWDR window register 0x7F 0x00 50D5 Reserved area (11 bytes) 0x01 0x00 50D6 WDG_PR IWDG prescaler register 0x00 0x00 50D7 Reserved area (13 bytes) 0x06	0x00 50C5		CLK_CCOR	CLK Configurable clock control register	0x00		
0x00 50C8 CLK_SWR CLK System clock switch register 0x01 0x00 50C9 CLK_SWCR CLK Clock switch control register 0x00 0x00 50CB CLK_CSSR CLK Clock security system register 0x00 0x00 50CB CLK_CBEEPR CLK Clock BEEP register 0x00 0x00 50CD CLK_HSICALR CLK HSI calibration register 0xXX 0x00 50CE CLK_HSITRIMR CLK HSI calibration trimming register 0x00 0x00 50CE CLK_REGCSR CLK Main regulator control status register 0x00 0x00 50D1 CLK_PCKENR3 CLK Peripheral clock gating register 3 0x00 0x00 50D1 CLK_PCKENR3 CLK Peripheral clock gating register 3 0x00 0x00 50D2 Reserved area (2 bytes) 0x7F 0x00 50D4 WWDG_WR WWDG control register 0x7F 0x00 50D5 WWDG_WR WWDR window register 0x7F 0x00 50D6 WWDG_MR IWDG key register 0x01 0x00 50E1 IWDG IWDG_RR IWDG key register 0x01 0x00 50E2 IWDG_RR	0x00 50C6		CLK_ECKCR	CLK External clock control register	0x00		
0x00 50C9 CLK CLK_SWCR CLK Clock switch control register 0xx0 0x00 50CB CLK CLK_CSSR CLK Clock security system register 0x00 0x00 50CC CLK_CBEEPR CLK Clock BEEP register 0x00 0x00 50CD CLK_HSICALR CLK HSI calibration register 0x0X 0x00 50CE CLK_HSITRIMR CLK HSI clock calibration trimming register 0x00 0x00 50CE CLK_HSIUNLCKR CLK HSI unlock register 0x00 0x00 50D0 CLK_PCKENR3 CLK Peripheral clock gating register 0x00 0x00 50D1 Total Color Co	0x00 50C7		CLK_SCSR	CLK System clock status register	0x01		
Ox00 50CA OX00 50CB OX00 50CC OX00	0x00 50C8		CLK_SWR	CLK System clock switch register	0x01		
Ox00 50CB	0x00 50C9		CLK_SWCR	CLK Clock switch control register	0xX0		
0x00 50CB CLK_CBEEPR CLK Clock BEEP register 0x00 0x00 50CC CLK_HSICALR CLK HSI calibration register 0x00 0x00 50CE CLK_HSIUNLCKR CLK HSI unlock register 0x00 0x00 50CF CLK_REGCSR CLK Main regulator control status register 0x0x0 0x00 50D0 CLK_PCKENR3 CLK Peripheral clock gating register 3 0x00 0x00 50D1 to 0x00 50D2 WWDG Reserved area (2 bytes) 0x7F 0x00 50D3 WWDG WWDG_CR WWDG control register 0x7F 0x00 50D4 to 00 50D5 to 00 50D6 to 00 50D6 to 00 50D6 WWDG_WR WWDG window register 0x7F 0x00 50E0 IWDG IWDG_RR IWDG key register 0x00 0x00 50E1 IWDG IWDG_PR IWDG prescaler register 0x00 0x00 50E2 IWDG_RR IWDG reload register 0x0F 0x00 50E2 BEEP_CSR1 BEEP control/status register 1 0x00 0x00 50E3 Reserved area (13 bytes) 0x0 0x00 50F1 RESEP_CSR2 BEEP control/status register 2 0x1F <tr< td=""><td>0x00 50CA</td><td>CLK</td><td>CLK_CSSR</td><td>CLK Clock security system register</td><td>0x00</td></tr<>	0x00 50CA	CLK	CLK_CSSR	CLK Clock security system register	0x00		
0x00 50CD CLK_HSITRIMR CLK HSI clock calibration trimming register 0x00 0x00 50CE CLK_HSIUNLCKR CLK HSI unlock register 0x00 0x00 50CF CLK_REGCSR CLK Main regulator control status register 0bxx11 1 0x 0x00 50D0 CLK_PCKENR3 CLK Peripheral clock gating register 3 0x00 0x00 50D1 to 0x00 50D2 WWDG_CR WWDG control register 0x7F 0x00 50D3 WWDG_WR WWDR window register 0x7F 0x00 50D4 to 00 50D5 to 00 50DF IWDG_KR IWDG key register 0x01 0x00 50E0 0x00 50E1 to 0x00 50E2 IWDG_PR IWDG prescaler register 0x00 0x00 50E2 0x00 50E2 to 0x00 50E5 to 0x00 50E6 Reserved area (13 bytes) 0xFF 0x00 50F0 0x00 50F1 0x00 50F2 0x00 50F2 0x00 50F2 0x00 50F3 BEEP_CSR1 BEEP_control/status register 1 0x00 0x00 50F3 0x00 50F4 to 0x00 50F4 to 0x00 5140 0x00 5140 0x00 5140 0x00 5141 RTC_TR1 RTC_TR1 RTC Time register 1 0x00 0x00 5140 0x00 5141 RTC RTC_TR2 RTC Time register 2 0x00	0x00 50CB	0 \	CLK_CBEEPR	CLK Clock BEEP register	0x00		
CLK_HSIUNLCKR CLK HSI unlock register 0x00	0x00 50CC		CLK_HSICALR	CLK HSI calibration register	0xXX		
0x00 50CF CLK_REGCSR CLK Main regulator control status register 0bxx11 1 00X 1 0X 1	0x00 50CD		CLK_HSITRIMR	CLK HSI clock calibration trimming register	0x00		
CLK_REGCSR CLK Main regulator control status register 00X	0x00 50CE		CLK_HSIUNLCKR	CLK HSI unlock register	0x00		
Nove	0x00 50CF		CLK_REGCSR	CLK Main regulator control status register			
to 0x00 50D2 Reserved area (2 bytes) 0x00 50D3 0x00 50D4 0x00 50D4 0x00 50D5 to 0x00 50DF WWDG_WR WWDG window register 0x7F 0x00 50D5 to 0x00 50DF 0x00 50DF 0x00 50E0 0x00 50E2 0x00 50E2 0x00 50E3 to 0x00 50E2 0x00 50E3 to 0x00 50E3 to 0x00 50E5 0x00 50E3 to 0x00 50E5 0x00 50E6 0x00 50E7 0x00 50E6 0x00 50E7 0x00	0x00 50D0		CLK_PCKENR3	CLK Peripheral clock gating register 3	0x00		
0x00 50D4 WWDG WWDG_WR WWDR window register 0x7F 0x00 50D5 to 00 50DF Reserved area (11 bytes) 0x01 0x00 50E0 0x00 50E1 IWDG_KR IWDG key register 0x01 0x00 50E2 0x00 50E2 IWDG_PR IWDG prescaler register 0x00 0x00 50E3 to 0x00 50E3 to 0x00 50F0 Reserved area (13 bytes) 0xFF 0x00 50F1 0x00 50F2 BEEP_CSR1 BEEP control/status register 1 0x00 0x00 50F3 BEEP_CSR2 BEEP control/status register 2 0x1F 0x00 50F4 to0x00 513F Reserved area (76 bytes) 0x00 0x00 5140 RTC_TR1 RTC Time register 1 0x00 0x00 5141 RTC RTC_TR2 RTC Time register 2 0x00	to		Reserved area (2 bytes)				
0x00 50D4 WWDG_WR WWDR window register 0x7F 0x00 50D5 to 00 50DF to 00 50DF Reserved area (11 bytes) 0x00 50E0 0x01 0x00 50E0 IWDG_KR IWDG key register 0x01 0x00 50E1 IWDG_PR IWDG prescaler register 0x00 0x00 50E2 IWDG_RLR IWDG reload register 0xFF 0x00 50E3 to 0x00 50E5 Reserved area (13 bytes) 0x00 0x00 50F0 0x00 50F1 0x00 50F2 BEEP_CSR1 BEEP control/status register 1 0x00 0x00 50F3 0x00 50F4 to 0x00 513F Reserved area (76 bytes) 0x00 0x00 5140 0x00 5140 0x00 5141 RTC_TR1 RTC Time register 1 0x00 0x00 5141 RTC RTC_TR2 RTC Time register 2 0x00	0x00 50D3	WWDG	WWDG_CR	WWDG control register	0x7F		
to 00 50DF Reserved area (11 bytes) 0x00 50E0 0x00 50E1 0x00 50E2 0x00 50E2 0x00 50E2 0x00 50E3 0x00 50F6 0x00 50F1 0x00 50F2 0x00 50F2 0x00 50F3 0x00 50F4 to0x00 513F IWDG_KR IWDG prescaler register 0x00 0x0F IWDG_RLR IWDG reload register 0xFF 0x00 50E3 0x00 50F0 0x00 50F1 0x00 50F2 0x00 50F3 0x00 50F4 to0x00 513F BEEP_CSR1 BEEP control/status register 1 0x00 BEEP_CSR2 BEEP control/status register 2 0x1F 0x00 50F4 to0x00 513F Reserved area (76 bytes) 0x00 5140 0x00 5141 RTC_TR1 RTC Time register 1 0x00 0x00 5141 RTC_TR2 RTC Time register 2 0x00	0x00 50D4	VVVDG	WWDG_WR	WWDR window register	0x7F		
0x00 50E1 IWDG IWDG_PR IWDG prescaler register 0x00 0x00 50E2 IWDG_RLR IWDG reload register 0xFF 0x00 50E3 to 0x00 50EF Reserved area (13 bytes) 0x00 0x00 50F0 0x00 50F1 0x00 50F2 BEEP_CSR1 BEEP control/status register 1 0x00 0x00 50F3 0x00 50F4 to0x00 513F BEEP_CSR2 BEEP control/status register 2 0x1F 0x00 5140 0x00 5140 RTC_TR1 RTC Time register 1 0x00 0x00 0x00 5141 RTC RTC_TR2 RTC Time register 2 0x00	to		Reserved area (11 bytes)				
0x00 50E2 IWDG_RLR IWDG reload register 0xFF 0x00 50E3 to 0x00 50EF Reserved area (13 bytes) 0x00 50F0 0x00 50F0 0x00 50F1 0x00 50F2 BEEP_CSR1 BEEP control/status register 1 0x00 0x00 50F3 0x00 50F3 0x00 50F4 to0x00 513F BEEP_CSR2 BEEP control/status register 2 0x1F 0x00 5140 0x00 5140 RTC_TR1 RTC Time register 1 0x00 0x00 0x00 5141 RTC RTC_TR2 RTC Time register 2 0x00	0x00 50E0		IWDG_KR	IWDG key register	0x01		
0x00 50E3 to 0x00 50EF Reserved area (13 bytes) 0x00 50F0 BEEP_CSR1 BEEP control/status register 1 0x00 0x00 50F1 0x00 50F2 BEEP_CSR2 BEEP control/status register 2 0x1F 0x00 50F3 BEEP_CSR2 BEEP control/status register 2 0x1F 0x00 50F4 to0x00 513F Reserved area (76 bytes) 0x00 5140 RTC_TR1 RTC Time register 1 0x00 0x00 5141 RTC RTC_TR2 RTC Time register 2 0x00	0x00 50E1	IWDG	IWDG_PR	IWDG prescaler register	0x00		
to 0x00 50EF Reserved area (13 bytes) 0x00 50F0 BEEP_CSR1 BEEP control/status register 1 0x00 0x00 50F1 0x00 50F2 BEEP_CSR2 BEEP control/status register 2 0x1F 0x00 50F3 0x00 50F4 to0x00 513F Reserved area (76 bytes) Reserved area (76 bytes) 0x00 5140 0x00 5141 RTC_TR1 RTC Time register 1 0x00 0x00 5141 RTC RTC_TR2 RTC Time register 2 0x00	0x00 50E2		IWDG_RLR	IWDG reload register	0xFF		
0x00 50F1 0x00 50F2 BEEP Reserved area (2 bytes) 0x00 50F3 BEEP_CSR2 BEEP control/status register 2 0x1F 0x00 50F4 to0x00 513F Reserved area (76 bytes) 0x00 5140 RTC_TR1 RTC Time register 1 0x00 0x00 5141 RTC RTC_TR2 RTC Time register 2 0x00	to	Reserved area (13 bytes)					
0x00 50F2 BEEP Reserved area (2 bytes) 0x00 50F3 BEEP_CSR2 BEEP control/status register 2 0x1F 0x00 50F4 t00x00 513F Reserved area (76 bytes) 0x00 5140 RTC_TR1 RTC Time register 1 0x00 0x00 5141 RTC RTC_TR2 RTC Time register 2 0x00	0x00 50F0		BEEP_CSR1	BEEP control/status register 1	0x00		
0x00 50F4 t00x00 513F Reserved area (76 bytes) 0x00 5140 RTC_TR1 RTC Time register 1 0x00 0x00 5141 RTC RTC_TR2 RTC Time register 2 0x00		BEEP		Reserved area (2 bytes)			
to0x00 513F Reserved area (76 bytes) 0x00 5140 RTC_TR1 RTC Time register 1 0x00 0x00 5141 RTC RTC_TR2 RTC Time register 2 0x00	0x00 50F3		BEEP_CSR2	BEEP control/status register 2	0x1F		
0x00 5141 RTC RTC_TR2 RTC Time register 2 0x00		Reserved area (76 bytes)					
	0x00 5140		RTC_TR1	RTC Time register 1	0x00		
0x00 5142 RTC_TR3 RTC Time register 3 0x00	0x00 5141	RTC	RTC_TR2	RTC Time register 2	0x00		
	0x00 5142		RTC_TR3	RTC Time register 3	0x00		



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Table 7. General hardware register map (continued)

Address	Block	Register label	Register name	Reset status
0x00 5143			Reserved area (1 byte)	
0x00 5144		RTC_DR1	RTC Date register 1	0x01
0x00 5145		RTC_DR2	RTC Date register 2	0x21
0x00 5146		RTC_DR3	RTC Date register 3	0x00
0x00 5147			Reserved area (1 byte)	
0x00 5148		RTC_CR1	RTC Control register 1	0x00 ⁽¹⁾
0x00 5149		RTC_CR2	RTC Control register 2	0x00 ⁽¹⁾
0x00 514A		RTC_CR3	RTC Control register 3	0x00 ⁽¹⁾
0x00 514B			Reserved area (1 byte)	1
0x00 514C		RTC_ISR1	RTC Initialization and status register 1	0x01
0x00 514D		RTC_ISR2	RTC Initialization and Status register 2	0x00
0x00 514E 0x00 514F			Reserved area (2 bytes)	
0x00 5150		RTC_SPRERH	RTC Synchronous prescaler register high	0x00 ⁽¹⁾
0x00 5151		RTC_SPRERL	RTC Synchronous prescaler register low	0xFF ⁽¹⁾
0x00 5152		RTC_APRER	RTC Asynchronous prescaler register	0x7F ⁽¹⁾
0x00 5153			Reserved area (1 byte)	
0x00 5154	RTC	RTC_WUTRH	RTC Wakeup timer register high	0xFF ⁽¹⁾
0x00 5155		RTC_WUTRL	RTC Wakeup timer register low	0xFF ⁽¹⁾
0x00 5156			Reserved area (1 byte)	
0x00 5157		RTC_SSRL	RTC Subsecond register low	0x00
0x00 5158		RTC_SSRH	RTC Subsecond register high	0x00
0x00 5159		RTC_WPR	RTC Write protection register	0x00
0x00 5158		RTC_SSRH	RTC Subsecond register high	0x00
0x00 5159		RTC_WPR	RTC Write protection register	0x00
0x00 515A		RTC_SHIFTRH	RTC Shift register high	0x00
0x00 515B		RTC_SHIFTRL	RTC Shift register low	0x00
0x00 515C		RTC_ALRMAR1	RTC Alarm A register 1	0x00 ⁽¹⁾
0x00 515D		RTC_ALRMAR2	RTC Alarm A register 2	0x00 ⁽¹⁾
0x00 515E		RTC_ALRMAR3	RTC Alarm A register 3	0x00 ⁽¹⁾
0x00 515F		RTC_ALRMAR4	RTC Alarm A register 4	0x00 ⁽¹⁾
0x00 5160 to 0x00 5163			Reserved area (4 bytes)	
0x00 5164		RTC_ALRMASSRH	RTC Alarm A subsecond register high	0x00 ⁽¹⁾
0x00 5165		RTC_ALRMASSRL	RTC Alarm A subsecond register low	0x00 ⁽¹⁾



Table 7. General hardware register map (continued)

Address	Block	Register label	Register name	Reset status	
0x00 5166		RTC_ALRMASSMSKR	RTC Alarm A masking register	0x00 ⁽¹⁾	
0x00 5167 to 0x00 5169		Reserved area (3 bytes)			
0x00 516A		RTC_CALRH	RTC Calibration register high	0x00 ⁽¹⁾	
0x00 516B	RTC	RTC_CALRL	RTC Calibration register low	0x00 ⁽¹⁾	
0x00 516C	RIC	RTC_TCR1	RTC Tamper control register 1	0x00 ⁽¹⁾	
0x00 516D		RTC_TCR2	RTC Tamper control register 2	0x00 ⁽¹⁾	
0x00 516E to 0x00 518A		Reserved area (36 bytes)			
0x00 5190		CSSLSE_CSR	CSS on LSE control and status register	0x00 ⁽¹⁾	
0x00 519A to 0x00 51FF		Re	eserved area (111 bytes)		
0x00 5200		SPI1_CR1	SPI1 control register 1	0x00	
0x00 5201		SPI1_CR2	SPI1 control register 2	0x00	
0x00 5202		SPI1_ICR	SPI1 interrupt control register	0x00	
0x00 5203	SPI1	SPI1_SR	SPI1 status register	0x02	
0x00 5204	5811	SPI1_DR	SPI1 data register	0x00	
0x00 5205		SPI1_CRCPR	SPI1 CRC polynomial register	0x07	
0x00 5206		SPI1_RXCRCR	SPI1 Rx CRC register	0x00	
0x00 5207	•	SPI1_TXCRCR	SPI1 Tx CRC register	0x00	
0x00 5208 to 0x00 520F		Reserved area (8 bytes)			
0x00 5210		I2C1_CR1	I2C1 control register 1	0x00	
0x00 5211		I2C1_CR2	I2C1 control register 2	0x00	
0x00 5212		I2C1_FREQR	I2C1 frequency register	0x00	
0x00 5213		I2C1_OARL	I2C1 own address register low	0x00	
0x00 5214		I2C1_OARH	I2C1 own address register high	0x00	
0x00 5215	I2C1	I2C1_OAR2	I2C1 own address register for dual mode	0x00	
0x00 5216		I2C1_DR	I2C1 data register	0x00	
0x00 5217		I2C1_SR1	I2C1 status register 1	0x00	
0x00 5218		I2C1_SR2	I2C1 status register 2	0x00	
0x00 5219		I2C1_SR3	I2C1 status register 3	0x0X	
0x00 521A		I2C1_ITR	I2C1 interrupt control register	0x00	
0x00 521B		I2C1_CCRL	I2C1 clock control register low	0x00	
0x00 521C		I2C1_CCRH	I2C1 clock control register high	0x00	



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Table 7. General hardware register map (continued)

Address	Block	Register label	Register name	Reset
	2.00		103.000	status
0x00 521D	I2C1	I2C1_TRISER	I2C1 TRISE register	0x02
0x00 521E		I2C1_PECR	I2C1 packet error checking register	0x00
0x00 521F to 0x00 522F		R	Reserved area (17 bytes)	
0x00 5230		USART1_SR	USART1 status register	0xC0
0x00 5231		USART1_DR	USART1 data register	0xXX
0x00 5232		USART1_BRR1	USART1 baud rate register 1	0x00
0x00 5233		USART1_BRR2	USART1 baud rate register 2	0x00
0x00 5234		USART1_CR1	USART1 control register 1	0x00
0x00 5235	USART1	USART1_CR2	USART1 control register 2	0x00
0x00 5236		USART1_CR3	USART1 control register 3	0x00
0x00 5237		USART1_CR4	USART1 control register 4	0x00
0x00 5238		USART1_CR5	USART1 control register 5	0x00
0x00 5239		USART1_GTR	USART1 guard time register	0x00
0x00 523A		USART1_PSCR	USART1 prescaler register	0x00
0x00 523B to 0x00 524F		R	Reserved area (21 bytes)	
0x00 5250		TIM2_CR1	TIM2 control register 1	0x00
0x00 5251		TIM2_CR2	TIM2 control register 2	0x00
0x00 5252		TIM2_SMCR	TIM2 Slave mode control register	0x00
0x00 5253		TIM2_ETR	TIM2 external trigger register	0x00
0x00 5254		TIM2_DER	TIM2 DMA1 request enable register	0x00
0x00 5255		TIM2_IER	TIM2 interrupt enable register	0x00
0x00 5256		TIM2_SR1	TIM2 status register 1	0x00
0x00 5257	TIMO	TIM2_SR2	TIM2 status register 2	0x00
0x00 5258	TIM2	TIM2_EGR	TIM2 event generation register	0x00
0x00 5259		TIM2_CCMR1	TIM2 capture/compare mode register 1	0x00
0x00 525A		TIM2_CCMR2	TIM2 capture/compare mode register 2	0x00
0x00 525B		TIM2_CCER1	TIM2 capture/compare enable register 1	0x00
0x00 525C		TIM2_CNTRH	TIM2 counter high	0x00
0x00 525D		TIM2_CNTRL	TIM2 counter low	0x00
0x00 525E		TIM2_PSCR	TIM2 prescaler register	0x00
0x00 525F		TIM2_ARRH	TIM2 auto-reload register high	0xFF



Table 7. General hardware register map (continued)

Address	Block	Register label	Register name	Reset status
0x00 5260		TIM2_ARRL	TIM2 auto-reload register low	0xFF
0x00 5261		TIM2_CCR1H	TIM2 capture/compare register 1 high	0x00
0x00 5262		TIM2_CCR1L	TIM2 capture/compare register 1 low	0x00
0x00 5263	TIM2	TIM2_CCR2H	TIM2 capture/compare register 2 high	0x00
0x00 5264		TIM2_CCR2L	TIM2 capture/compare register 2 low	0x00
0x00 5265		TIM2_BKR	TIM2 break register	0x00
0x00 5266		TIM2_OISR	TIM2 output idle state register	0x00
0x00 5267 to 0x00 527F		F	Reserved area (25 bytes)	•
0x00 5280		TIM3_CR1	TIM3 control register 1	0x00
0x00 5281		TIM3_CR2	TIM3 control register 2	0x00
0x00 5282		TIM3_SMCR	TIM3 Slave mode control register	0x00
0x00 5283		TIM3_ETR	TIM3 external trigger register	0x00
0x00 5284		TIM3_DER	TIM3 DMA1 request enable register	0x00
0x00 5285		TIM3_IER	TIM3 interrupt enable register	0x00
0x00 5286		TIM3_SR1	TIM3 status register 1	0x00
0x00 5287		TIM3_SR2	TIM3 status register 2	0x00
0x00 5288		TIM3_EGR	TIM3 event generation register	0x00
0x00 5289		TIM3_CCMR1	TIM3 Capture/Compare mode register 1	0x00
0x00 528A		TIM3_CCMR2	TIM3 Capture/Compare mode register 2	0x00
0x00 528B	TIM3	TIM3_CCER1	TIM3 Capture/Compare enable register 1	0x00
0x00 528C		TIM3_CNTRH	TIM3 counter high	0x00
0x00 528D		TIM3_CNTRL	TIM3 counter low	0x00
0x00 528E		TIM3_PSCR	TIM3 prescaler register	0x00
0x00 528F		TIM3_ARRH	TIM3 Auto-reload register high	0xFF
0x00 5290		TIM3_ARRL	TIM3 Auto-reload register low	0xFF
0x00 5291		TIM3_CCR1H	TIM3 Capture/Compare register 1 high	0x00
0x00 5292		TIM3_CCR1L	TIM3 Capture/Compare register 1 low	0x00
0x00 5293		TIM3_CCR2H	TIM3 Capture/Compare register 2 high	0x00
0x00 5294		TIM3_CCR2L	TIM3 Capture/Compare register 2 low	0x00
0x00 5295		TIM3_BKR	TIM3 break register	0x00
0x00 5296		TIM3_OISR	TIM3 output idle state register	0x00
0x00 5297 to 0x00 52DF		F	Reserved area (72 bytes)	



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Table 7. General hardware register map (continued)

Address	Block	Register label	Register name	Reset status	
0x00 52E0		TIM4_CR1	TIM4 control register 1	0x00	
0x00 52E1		TIM4_CR2	TIM4 control register 2	0x00	
0x00 52E2		TIM4_SMCR	TIM4 Slave mode control register	0x00	
0x00 52E3		TIM4_DER	TIM4 DMA1 request enable register	0x00	
0x00 52E4	TIM4	TIM4_IER	TIM4 Interrupt enable register	0x00	
0x00 52E5		TIM4_SR1	TIM4 status register 1	0x00	
0x00 52E6		TIM4_EGR	TIM4 Event generation register	0x00	
0x00 52E7		TIM4_CNTR	TIM4 counter	0x00	
0x00 52E8		TIM4_PSCR	TIM4 prescaler register	0x00	
0x00 52E9		TIM4_ARR	TIM4 Auto-reload register	0x00	
0x00 52EA to 0x00 52FE		Reserved area (21 bytes)			
0x00 52FF	IRTIM	IR_CR	Infrared control register	0x00	
0x00 5317 to 0x00 533F		F	Reserved area (41 bytes)		
0x00 5340		ADC1_CR1	ADC1 configuration register 1	0x00	
0x00 5341		ADC1_CR2	ADC1 configuration register 2	0x00	
0x00 5342		ADC1_CR3	ADC1 configuration register 3	0x1F	
0x00 5343		ADC1_SR	ADC1 status register	0x00	
0x00 5344		ADC1_DRH	ADC1 data register high	0x00	
0x00 5345		ADC1_DRL	ADC1 data register low	0x00	
0x00 5346		ADC1_HTRH	ADC1 high threshold register high	0x0F	
0x00 5347		ADC1_HTRL	ADC1 high threshold register low	0xFF	
0x00 5348	ADC1	ADC1_LTRH	ADC1 low threshold register high	0x00	
0x00 5349	ADCT	ADC1_LTRL	ADC1 low threshold register low	0x00	
0x00 534A		ADC1_SQR1	ADC1 channel sequence 1 register	0x00	
0x00 534B		ADC1_SQR2	ADC1 channel sequence 2 register	0x00	
0x00 534C		ADC1_SQR3	ADC1 channel sequence 3 register	0x00	
0x00 534D	ADC1_SQR4		ADC1 channel sequence 4 register	0x00	
0x00 534E		ADC1_TRIGR1	ADC1 trigger disable 1	0x00	
0x00 534F		ADC1_TRIGR2	ADC1 trigger disable 2	0x00	
0x00 5350		ADC1_TRIGR3	ADC1 trigger disable 3	0x00	
0x00 5351		ADC1_TRIGR4	ADC1 trigger disable 4	0x00	



Table 7. General hardware register map (continued)

Address	Block	Register label	Register name	Reset status
0x00 53C8 to 0x00 542F			Reserved area(104 bytes)	
0x00 5430			Reserved area (1 byte)	0x00
0x00 5431		RI_ICR1	RI Timer input capture routing register 1	0x00
0x00 5432		RI_ICR2	RI Timer input capture routing register 2	0x00
0x00 5433		RI_IOIR1	RI I/O input register 1	0xXX
0x00 5434		RI_IOIR2	RI I/O input register 2	0xXX
0x00 5435		RI_IOIR3	RI I/O input register 3	0xXX
0x00 5436		RI_IOCMR1	RI I/O control mode register 1	0x00
0x00 5437	RI	RI_IOCMR2	RI I/O control mode register 2	0x00
0x00 5438	KI	RI_IOCMR3	RI I/O control mode register 3	0x00
0x00 5439		RI_IOSR1	RI I/O switch register 1	0x00
0x00 543A		RI_IOSR2	RI I/O switch register 2	0x00
0x00 543B		RI_IOSR3	RI I/O switch register 3	0x00
0x00 543C		RI_IOGCR	RI I/O group control register	0xFF
0x00 543D		RI_ASCR1	Analog switch register 1	0x00
0x00 543E		RI_ASCR2	RI Analog switch register 2	0x00
0x00 543F		RI_RCR	RI Resistor control register	0x00
0x00 5440		COMP_CSR1	Comparator control and status register 1	0x00
0x00 5441		COMP_CSR2	Comparator control and status register 2	0x00
0x00 5442	COMP1/ COMP2	COMP_CSR3	Comparator control and status register 3	0x00
0x00 5443		COMP_CSR4	Comparator control and status register 4	0x00
0x00 5444		COMP_CSR5	Comparator control and status register 5	0x00
0x00 5445 to 0x00 544F			Reserved area (16 bytes)	
0x00 5450		RI_CR	RI I/O control register	0x00
0x00 5451		RI_MASKR1	RI I/O mask register 1	0x00
0x00 5452		RI_MASKR2	RI I/O mask register 2	0x00
0x00 5453	RI	RI_MASKR3	RI I/O mask register 3	0x00
0x00 5454	KI	RI_MASKR4	RI I/O mask register 4	0x00
0x00 5455		RI_IOIR4	RI I/O input register 4	0xXX
0x00 5456		RI_IOCMR4	RI I/O control mode register 4	0x00
0x00 5457		RI_IOSR4	RI I/O switch register 4	0x00

^{1.} These registers are not impacted by a system reset. They are reset at power-on.



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Table 8. CPU/SWIM/debug module/interrupt controller registers

Address	Block	Register label	Register name	Reset status
0x00 7F00		A	Accumulator	0x00
0x00 7F01		PCE	Program counter extended	0x00
0x00 7F02		PCH	Program counter high	0x00
0x00 7F03		PCL	Program counter low	0x00
0x00 7F04		XH	X index register high	0x00
0x00 7F05	CPU ⁽¹⁾	XL	X index register low	0x00
0x00 7F06		YH	Y index register high	0x00
0x00 7F07		YL	Y index register low	0x00
0x00 7F08		SPH	Stack pointer high	0x03
0x00 7F09		SPL	Stack pointer low	0xFF
0x00 7F0A		CCR	Condition code register	0x28
0x00 7F0B to 0x00 7F5F	CPU		Reserved area (85 bytes)	
0x00 7F60		CFG_GCR Global configuration register		0x00
0x00 7F70		ITC_SPR1	Interrupt Software priority register 1	0xFF
0x00 7F71		ITC_SPR2	Interrupt Software priority register 2	0xFF
0x00 7F72		ITC_SPR3	Interrupt Software priority register 3	0xFF
0x00 7F73	ITC-SPR	ITC_SPR4	Interrupt Software priority register 4	0xFF
0x00 7F74	110-511	ITC_SPR5	Interrupt Software priority register 5	0xFF
0x00 7F75		ITC_SPR6	Interrupt Software priority register 6	0xFF
0x00 7F76	ITC_SPR7 Interrupt Software priority register		Interrupt Software priority register 7	0xFF
0x00 7F77		ITC_SPR8	Interrupt Software priority register 8	0xFF
0x00 7F78 to 0x00 7F79		ı	Reserved area (2 bytes)	
0x00 7F80	SWIM	SWIM_CSR	SWIM control status register	0x00
0x00 7F81 to		F	Reserved area (15 bytes)	
0x00 7F8F				T
0x00 7F90		DM_BK1RE	DM breakpoint 1 register extended byte	0xFF
0x00 7F91		DM_BK1RH	DM breakpoint 1 register high byte	0xFF
0x00 7F92	D	DM_BK1RL	DM breakpoint 1 register low byte	0xFF
0x00 7F93	DM	DM_BK2RE	DM breakpoint 2 register extended byte	0xFF
0x00 7F94		DM_BK2RH	DM breakpoint 2 register high byte	0xFF
0x00 7F95		DM_BK2RL	DM breakpoint 2 register low byte	0xFF
0x00 7F96		DM_CR1	DM Debug module control register 1	0x00



Table 8. CPU/SWIM/debug module/interrupt controller registers (continued)

Address	Block	Register label	Register name	Reset status
0x00 7F97		DM_CR2	DM Debug module control register 2	0x00
0x00 7F98	DM	DM_CSR1	DM Debug module control/status register 1	0x10
0x00 7F99	DIVI	DM_CSR2	DM Debug module control/status register 2	0x00
0x00 7F9A		DM_ENFCTR	DM enable function register	0xFF
0x00 7F9B to 0x00 7F9F		F	Reserved area (5 bytes)	

^{1.} Accessible by debug module only



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6 Interrupt vector mapping

The interrupt vector mapping is described in *Table 9*.

Table 9. Interrupt mapping

	Table 9. Interrupt mapping							
IRQ No.	Source block	Description	Wakeup from Halt mode	Wakeup from Active-halt mode	Wakeup from Wait (WFI mode)	Wakeup from Wait (WFE mode) ⁽¹⁾	Vector address	
	RESET	Reset	Yes	Yes	Yes	Yes	0x00 8000	
	TRAP	Software interrupt	1	-	i	1	0x00 8004	
0	TLI ⁽²⁾	External Top level Interrupt	-	-	-	-	0x00 8008	
1	FLASH	FLASH end of programing/ write attempted to protected page interrupt	-	-	Yes	Yes	0x00 800C	
2	DMA1 0/1	DMA1 channels 0/1 half transaction/transaction complete interrupt	-	-	Yes	Yes	0x00 8010	
3	DMA1 2/3	DMA1 channels 2/3 half transaction/transaction complete interrupt	-	-	Yes	Yes	0x00 8014	
4	RTC	RTC alarm A/wakeup/ tamper 1/tamper 2/tamper 3	Yes	Yes	Yes	Yes	0x00 8018	
5	PVD	PVD interrupt	Yes	Yes	Yes	Yes	0x00 801C	
6	EXTIB	External interrupt port B	Yes	Yes	Yes	Yes	0x00 8020	
7	EXTID	External interrupt port D	Yes	Yes	Yes	Yes	0x00 8024	
8	EXTI0	External interrupt 0	Yes	Yes	Yes	Yes	0x00 8028	
9	EXTI1	External interrupt 1	Yes	Yes	Yes	Yes	0x00 802C	
10	EXTI2	External interrupt 2	Yes	Yes	Yes	Yes	0x00 8030	
11	EXTI3	External interrupt 3	Yes	Yes	Yes	Yes	0x00 8034	
12	EXTI4	External interrupt 4	Yes	Yes	Yes	Yes	0x00 8038	
13	EXTI5	External interrupt 5	Yes	Yes	Yes	Yes	0x00 803C	
14	EXTI6	External interrupt 6	Yes	Yes	Yes	Yes	0x00 8040	
15	EXTI7	External interrupt 7	Yes	Yes	Yes	Yes	0x00 8044	
16			Reserved				0x00 8048	
17	CLK	CLK system clock switch/CSS interrupt	-	-	Yes	Yes	0x00 804C	
18	ADC1	ACD1 end of conversion/ analog watchdog/ overrun interrupt	Yes	Yes	Yes	Yes	0x00 8050	



Table 9. Interrupt mapping (continued)

IRQ No.	Source block	Description	Wakeup from Halt mode	Wakeup from Active-halt mode	Wakeup from Wait (WFI mode)	Wakeup from Wait (WFE mode) ⁽¹⁾	Vector address
19	TIM2	TIM2 update /overflow/trigger/break interrupt	-	-	Yes	Yes	0x00 8054
20	TIM2	TIM2 Capture/Compare interrupt	-	-	Yes	Yes	0x00 8058
21	TIM3	TIM3 Update /Overflow/Trigger/Break interrupt	-	-	Yes	Yes	0x00 805C
22	TIM3	TIM3 Capture/Compare interrupt	-	-	Yes	Yes	0x00 8060
23	RI	RI trigger interrupt	-	-	Yes	-	0x00 8064
24			Reserved				0x00 8068
25	TIM4	TIM4 update/overflow/ trigger interrupt	-	-	Yes	Yes	0x00 806C
26	SPI1	SPI1 TX buffer empty/ RX buffer not empty/ error/wakeup interrupt	Yes	Yes	Yes	Yes	0x00 8070
27	USART 1	USART1 transmit data register empty/ transmission complete interrupt	-	-	Yes	Yes	0x00 8074
28	USART 1	USART1 received data ready/overrun error/ idle line detected/parity error/global error interrupt	-	-	Yes	Yes	0x00 8078
29	I2C1	I2C1 interrupt ⁽³⁾	Yes	Yes	Yes	Yes	0x00 807C

The Low-power wait mode is entered when executing a WFE instruction in Low-power run mode. In WFE mode, the
interrupt is served if it has been previously enabled. After processing the interrupt, the processor goes back to WFE mode.
When the interrupt is configured as a wakeup event, the CPU wakes up and resumes processing.

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^{2.} The TLI interrupt is the logic OR between TIM2 overflow interrupt, and TIM4 overflow interrupts.

^{3.} The device is woken up from Halt or Active-halt mode only when the address received matches the interface address.

Option bytes STM8L050J3

7 Option bytes

Option bytes contain configurations for device hardware features as well as the memory protection of the device. They are stored in a dedicated memory block.

All option bytes can be modified in ICP mode (with SWIM) by accessing the EEPROM address. See *Table 10* for details on option byte addresses.

The option bytes can also be modified 'on the fly' by the application in IAP mode, except for the ROP and UBCvalues which can only be taken into account when they are modified in ICP mode (with the SWIM).

Refer to the *How to program STM8L and STM8AL Flash program memory and data EEPROM* programming manual (PM0054) and the *STM8 SWIM communication protocol and debug module* user manual (UM0470) for information on SWIM programming procedures.

Table 10. Option byte addresses

Addr.	Ontion name	Option		Option bits				· · · · · · · · · · · · · · · · · · ·			Factory default
Addr.	Option name	byte No.	7	6	5	4	3	2	1	0	setting
0x00 4800	Read-out protection (ROP)	ОРТ0		ROP[7:0]					0xAA		
0x00 4802	UBC (User Boot code size)	OPT1				ı	UBC[7:0]				0x00
0x00 4807					Reserv	ed					0x00
0x00 4808	Independent watchdog option	OPT3 [3:0]		Reserved		WWDG _HALT	WWDG _HW	IWDG _HALT	IWDG _HW	0x00	
0x00 4809	Number of stabilization clock cycles for HSE and LSE oscillators	OPT4		Reserved LSECNT[1:0] HSECNT[1:0]			NT[1:0]	0x00			
0x00 480A	Brownout reset (BOR)	OPT5 [3:0]	Reserved			BOR_TH			BOR_ ON	0x00	
0x00 480B	Bootloader	OPTBL					0x00				
0x00 480C	option bytes (OPTBL)	[15:0]				OF	PTBL[15:0	נט			0x00

Ly/

STM8L050J3 Option bytes

Table 11. Option byte description

	lable 11. Option byte description
Option byte No.	Option description
	ROP[7:0] Memory readout protection (ROP)
OPT0	0xAA: Disable readout protection (write access via SWIM protocol) Refer to the "Readout protection" section in the STM8L050J3, STM8L051F3, STM8L052C6, STM8L052R8 MCUs and STM8L151/L152, STM8L162, STM8AL31, STM8AL3L lines reference manual (RM0031).
OPT1	UBC[7:0] Size of the user boot code area 0x00: UBC is not protected. 0x01: Page 0 is write protected. 0x02: Page 0 and 1 reserved for the UBC and write protected. It covers only the interrupt vectors. 0x03: Page 0 to 2 reserved for UBC and write protected. 0x7F to 0xFF - All 128 pages reserved for UBC and write protected. The protection of the memory area not protected by the UBC is enabled through the MASS keys. Refer to the "User boot code" section in the STM8L050J3, STM8L051F3, STM8L052C6, STM8L052R8 MCUs and STM8L151/L152, STM8L162, STM8AL31, STM8AL3L lines reference manual (RM0031).
OPT2	Reserved
	IWDG_HW: Independent watchdog 0: Independent watchdog activated by software 1: Independent watchdog activated by hardware
OPT3	IWDG_HALT: Independent window watchdog off on Halt/Active-halt 0: Independent watchdog continues running in Halt/Active-halt mode 1: Independent watchdog stopped in Halt/Active-halt mode
01 13	WWDG_HW: Window watchdog 0: Window watchdog activated by software 1: Window watchdog activated by hardware
	WWDG_HALT: Window window watchdog reset on Halt/Active-halt 0: Window watchdog stopped in Halt mode 1: Window watchdog generates a reset when MCU enters Halt mode
	HSECNT: Number of HSE oscillator stabilization clock cycles
	0x00 - 1 clock cycle 0x01 - 16 clock cycles 0x10 - 512 clock cycles 0x11 - 4096 clock cycles
OPT4	LSECNT: Number of LSE oscillator stabilization clock cycles 0x00 - 1 clock cycle 0x01 - 16 clock cycles 0x10 - 512 clock cycles 0x11 - 4096 clock cycles Refer to Table 29: LSE oscillator characteristics on page 64.



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Option bytes STM8L050J3

Table 11. Option byte description (continued)

Option byte No.	Option description
OPT5	BOR_ON: 0: Brownout reset off 1: Brownout reset on BOR_TH[3:1]: Brownout reset thresholds. Refer to <i>Table 20</i> for details on the thresholds according to
	the value of BOR_TH bits. OPTBL[15:0]:
OPTBL	This option is checked by the boot ROM code after reset. Depending on content of addresses 00 480B, 00 480C and 0x8000 (reset vector) the CPU jumps to the bootloader or to the reset vector. Refer to the UM0560 STM8 bootloader user manual for more details.

8 Electrical parameters

This section describes the quantification of the given device's parameters.

8.1 Parameter conditions

Unless otherwise specified, all voltages are referred to V_{SS}.

8.1.1 Minimum and maximum values

Unless otherwise specified the minimum and maximum values are guaranteed in the worst conditions of ambient temperature, supply voltage and frequencies by tests in production on 100% of the devices with an ambient temperature at T_A = 25 °C and T_A = T_A max (given by the selected temperature range).

Data based on characterization results, design simulation and/or technology characteristics is indicated in the table footnotes and are not tested in production. Based on characterization, the minimum and maximum values refer to sample tests and represent the mean value plus or minus three times the standard deviation (mean $\pm 3\Sigma$).

8.1.2 Typical values

Unless otherwise specified, typical data is based on T_A = 25 °C, V_{DD} = 3 V. It is given only as design guidelines and is not tested.

Typical ADC accuracy values are determined by characterization of a batch of samples from a standard diffusion lot over the full temperature range, where 95% of the devices have an error less than or equal to the value indicated (mean $\pm 2\Sigma$).

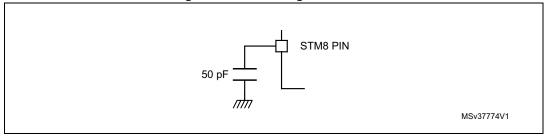
8.1.3 Typical curves

Unless otherwise specified, all typical curves are given only as design guidelines and are not tested.

8.1.4 Loading capacitor

The loading conditions used for pin parameter measurement are shown in *Figure 5*.

Figure 5. Pin loading conditions



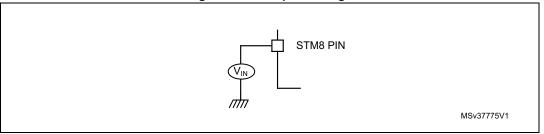
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8.1.5 Pin input voltage

The input voltage measurement on a pin of the device is described in Figure 6.

Figure 6. Pin input voltage



8.2 Absolute maximum ratings

Stresses above the absolute maximum ratings listed in *Table 12: Voltage characteristics*, *Table 13: Current characteristics*, and *Table 14: Thermal characteristics* may cause permanent damage to the device. These are stress ratings only and functional operation of the device at these conditions is not implied. Exposure to maximum rating conditions for extended periods may affect the device's reliability.

The device's mission profile (application conditions) is compliant with the JEDEC JESD47 Qualification Standard, extended mission profiles are available on demand.

Symbol	Ratings	Min	Max	Unit
V _{DD} - V _{SS}	External supply voltage (including $V_{\rm DDA}$) ⁽¹⁾	- 0.3	4.0	V
V _{IN} ⁽²⁾	Input voltage on any other pin	V _{ss} - 0.3	$V_{DD} + 0.3$	V
V _{ESD}	Electrostatic discharge voltage	see Absolute maximum ratings (electrical sensitivity) on page 87		-

Table 12. Voltage characteristics

All power (V_{DD1}, V_{DDA}) and ground (V_{SS1}, V_{SSA}) pins must always be connected to the external power supply.

^{2.} V_{IN} maximum must always be respected. Refer to *Table 13: Current characteristics* for maximum allowed injected current values.

Table 13. Current characteristics

Symbol	Ratings	Max.	Unit
I _{VDD}	Total current into V _{DD} power line (source)	80	
I _{VSS}	Total current out of V _{SS} ground line (sink)	80	
	Output current sunk by IR_TIM pin (with high sink LED driver capability)	80	
I _{IO}	Output current sunk by any other I/O and control pin	25	mA
	Output current sourced by any I/Os and control pin	- 25	
I _{INJ(PIN)}	Injected current on any pin ⁽¹⁾	- 5 / +5	
ΣI _{INJ(PIN)}	Total injected current (sum of all I/O and control pins) (2)	± 25	

^{1.} A positive injection is induced by $V_{IN} > V_{DD}$ while a negative injection is induced by $V_{IN} < V_{SS}$. $I_{INJ(PIN)}$ must never be exceeded. Refer to *Table 16*. for maximum allowed input voltage values.

Table 14. Thermal characteristics

Symbol	Ratings	Value	Unit
T _{STG}	Storage temperature range	-65 to +150	°C
TJ	Maximum junction temperature	150	C



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^{2.} When several inputs are submitted to a current injection, the maximum $\Sigma I_{INJ(PIN)}$ is the absolute sum of the positive and negative injected currents (instantaneous values).

8.3 Operating conditions

Subject to general operating conditions for V_{DD} and T_{A} .

8.3.1 General operating conditions

The operating conditions define the conditions under which the device operates correctly according to its specification (see *Table 15*).

Table 15. General operating conditions

Symbol	Parameter	Conditions	Min.	Max.	Unit
f _{SYSCLK} ⁽¹⁾	System clock frequency	1.8 V ≤ V _{DD} < 3.6 V	0	16	MHz
V _{DD}	Standard operating voltage	-	1.8	3.6	V
V_{DDA}	Analog operating voltage	Must be at the same potential as V _{DD}	1.8	3.6	V
P _D ⁽²⁾	Power dissipation at T _A = 125 °C	SO8N	-	49	mW
T _A	Temperature range	$1.8 \text{ V} \le \text{V}_{DD} < 3.6 \text{ V}$	-40	125	°C
T _J	Junction temperature range	-40 °C ≤ T _A < 125 °C	-40	130 ⁽³⁾	°C

^{1.} f_{SYSCLK} = f_{CPU}

To calculate P_{Dmax}(T_A), use the formula P_{Dmax}=(T_{Jmax} -T_A)/Θ_{JA} with T_{Jmax} in this table and Θ_{JA} in "Thermal characteristics" table.

^{3.} T_{Jmax} is given by the test limit. Above this value, the product behavior is not guaranteed.

8.3.2 Embedded reset and power control block characteristics

The reset and power block parameters are described in *Table 16* and are derived from tests performed under the ambient temperature conditions summarized in *Table 15: General operating conditions*.

Table 16. Embedded reset and power control block characteristics

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
4	V _{DD} rise time rate	BOR detector enabled	0 ⁽¹⁾	-	_∞ (1)	
t _{VDD}	V _{DD} fall time rate	BOR detector enabled	20 ⁽¹⁾	-	_∞ (1)	µs/V
t _{TEMP}	Reset release delay	V _{DD} rising	-	3	-	ms
V _{PDR}	Power-down reset threshold	Falling edge	1.30 ⁽²⁾	1.50	1.65	V
V	Brown-out reset threshold 0	Falling edge	1.67	1.70	1.74	
V _{BOR0}	(BOR_TH[2:0]=000)	Rising edge	1.69	1.75	1.80	
V	Brown-out reset threshold 1	Falling edge	1.87	1.93	1.97	
V _{BOR1}	(BOR_TH[2:0]=001)	Rising edge	1.96	2.04	2.07	
W	Brown-out reset threshold 2	Falling edge	2.22	2.3	2.35	V
V _{BOR2}	(BOR_TH[2:0]=010)	Rising edge	2.31	2.41	2.44	V
\/	Brown-out reset threshold 3 (BOR_TH[2:0]=011) Brown-out reset threshold 4	Falling edge	2.45	2.55	2.60	
VBOR3		Rising edge	2.54	2.66	2.7	
\/		Falling edge	2.68	2.80	2.85	
V _{BOR4}	(BOR_TH[2:0]=100)	Rising edge	2.78	2.90	2.95	
W	PVD threshold 0	Falling edge	1.80	1.84	1.88	
V _{PVD0}	F VD tillesiloid 0	Rising edge	1.88	1.94	1.99	
W	PVD threshold 1	Falling edge	1.98	2.04	2.09	
V _{PVD1}	T VD tillesilota i	Rising edge	2.08	2.14	2.18	
W	PVD threshold 2	Falling edge	2.2	2.24	2.28	
V _{PVD2}	F VD tillesiloid 2	Rising edge	2.28	2.34	2.38	
V _{PVD3}	PVD threshold 3	Falling edge	2.39	2.44	2.48	V
V PVD3	T VD tillesiloid 5	Rising edge	2.47	2.54	2.58	V
W	PVD threshold 4	Falling edge	2.57	2.64	2.69	
V _{PVD4}	1 AD (III C211010 4	Rising edge	2.68	2.74	2.79	
\/	PVD threshold 5	Falling edge	2.77	2.83	2.88	
V _{PVD5}	1. งก แเคยเดเตอ	Rising edge	2.87	2.94	2.99	
V	PVD threshold 6	Falling edge	2.97	3.05	3.09	
V _{PVD6}	า งก แเอยเดเต ถ	Rising edge	3.08	3.15	3.20	

^{1.} Guaranteed by design.

^{2.} Guaranteed by characterization results.



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Electrical parameters STM8L050J3

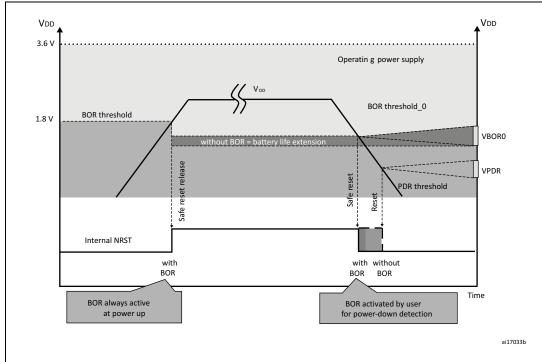


Figure 7. POR/BOR thresholds

8.3.3 Supply current characteristics

Total current consumption

The MCU is placed under the following conditions:

- \bullet All I/O pins in input mode with a static value at V_{DD} or V_{SS} (no load)
- All peripherals are disabled except if explicitly mentioned.

In the following table, data is based on characterization results, unless otherwise specified. Subject to general operating conditions for V_{DD} and T_A .



Table 17. Total current consumption in Run mode

Cumahad	Para		Conditions ⁽¹⁾		Torre		Max		11-0:4
Symbol	meter		Conditions ⁽¹⁾ Typ 55 °C 85 °C 125			125 °C	Unit		
				f _{CPU} = 125 kHz	0.39	0.47	0.49	0.55	
				f _{CPU} = 1 MHz	0.48	0.56	0.58	0.65	
	Supply current in run mode(2) All peripherals – OFF, code executed from RAM,		HSI RC osc. (16 MHz) ⁽³⁾	f _{CPU} = 4 MHz	0.75	0.84	0.86	0.99	
			(10 111112)	f _{CPU} = 8 MHz	1.10	1.20	1.25	1.40	
			f _{CPU} = 16 MHz	1.85	1.93	2.12 ⁽⁵⁾	2.36 ⁽⁵⁾		
			f _{CPU} = 125 kHz	0.05	0.06	0.09	0.12		
I _{DD(RUN)}		HSE external	f _{CPU} = 1 MHz	0.18	0.19	0.20	0.23	mA	
25(11011)		clock	f _{CPU} = 4 MHz	0.55	0.62	0.64	0.77		
V DD III	1.8 V to 3.6 V	V _{DD} from 1.8 V to 3.6 V (f _{CPU} =f _{HSE}) ⁽⁴⁾ LSI RC osc. (typ. 38 kHz)	f _{CPU} = 8 MHz	0.99	1.20	1.21	1.24		
			f _{CPU} = 16 MHz	1.90	2.22	2.23 ⁽⁵⁾	2.28 ⁽⁵⁾		
			f _{CPU} = f _{LSI}	0.040	0.045	0.046	0.050		
			LSE external clock (32.768 kHz)	f _{CPU} = f _{LSE}	0.035	0.040	0.048 ⁽⁵⁾	0.062	
				f _{CPU} = 125 kHz	0.43	0.55	0.56	0.62	
				f _{CPU} = 1 MHz	0.60	0.77	0.80	0.87	
			HSI RC osc. ⁽⁶⁾	f _{CPU} = 4 MHz	1.11	1.34	1.37	1.43	
				f _{CPU} = 8 MHz	1.90	2.20	2.23	2.40	
		All peripherals		f _{CPU} = 16 MHz	3.8	4.60	4.75	4.88	
	Supply current	OFF, code executed from		f _{CPU} = 125 kHz	0.30	0.36	0.39	0.47	
I _{DD(RUN)}	in Run	Flash,	HSE external	f _{CPU} = 1 MHz	0.40	0.50	0.52	0.56	mA
	mode	V _{DD} from 1.8 V to 3.6 V	clock	f _{CPU} = 4 MHz	1.15	1.31	1.40	1.48	
	1.0 V to 3.0 V	1.0 V to 3.0 V	(f _{CPU} =f _{HSE}) ⁽⁴⁾	f _{CPU} = 8 MHz	2.17	2.33	2.44	2.77	
				f _{CPU} = 16 MHz	4.0	4.46	4.52	4.77	
		LSI RC osc.	f _{CPU} = f _{LSI}	0.110	0.123	0.130	0.150		
			LSE ext. clock (32.768 kHz) ⁽⁷⁾	f _{CPU} = f _{LSE}	0.100	0.101	0.104	0.122	

^{1.} All peripherals OFF, $\rm V_{DD}$ from 1.8 V to 3.6 V, HSI internal RC osc. , $\rm f_{CPU} = f_{SYSCLK}$

5. Tested in production.



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^{2.} CPU executing typical data processing

^{3.} The run from RAM consumption can be approximated with the linear formula: $I_{DD}(run_from_RAM)$ = Freq * 90 $\mu A/MHz$ + 380 μA

Oscillator bypassed (HSEBYP = 1 in CLK_ECKCR). When configured for external crystal, the HSE consumption (I_{DD HSE}) must be added. Refer to *Table 28*.

STM8L050J3 **Electrical parameters**

- The run from Flash consumption can be approximated with the linear formula: $I_{DD}(run_from_Flash)$ = Freq * 195 $\mu A/MHz$ + 440 μA
- Oscillator bypassed (LSEBYP = 1 in CLK_ECKCR). When configured for extenal crystal, the LSE consumption ($I_{DD\ LSE}$) must be added. Refer to *Table* $\overline{29}$.

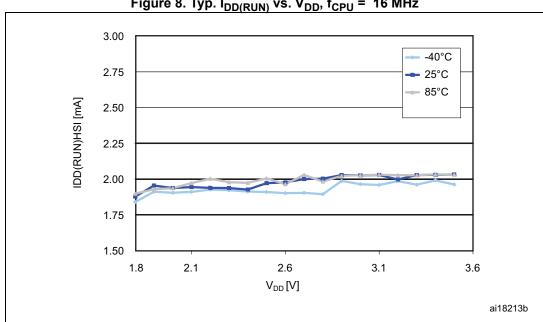


Figure 8. Typ. $I_{DD(RUN)}$ vs. V_{DD} , $f_{CPU} = 16 \text{ MHz}$

1. Typical current consumption measured with code executed from RAM

Table 18. Total current consumption in Wait mode

					_	Max			Unit
Symbol	Parameter		Conditions ⁽¹⁾		Тур	55°C	85°C	125°C	Onit
				f _{CPU} = 125 kHz	0.33	0.39	0.41	0.45	
				f _{CPU} = 1 MHz	0.35	0.41	0.44	0.48	
		HSI	f _{CPU} = 4 MHz	0.42	0.51	0.52	0.58		
	CPU not		f _{CPU} = 8 MHz	0.52	0.57	0.58	0.62		
		clocked, all peripherals		f _{CPU} = 16 MHz	0.68	0.76	0.79	0.85	
	Cummbu	OFF,		f _{CPU} = 125 kHz	0.032	0.056	0.068	0.093	
I _{DD(Wait)} current in from R/	code executed from RAM	HSE external	f _{CPU} = 1 MHz	0.078	0.121	0.144	0.197	mA	
	Wait mode	with Flash in	clock	f _{CPU} = 4 MHz	0.218	0.26	0.30	0.40	
	I _{DDQ} mode ⁽²⁾ , V _{DD} from	(f _{CPU} =f _{HSE}) ⁽³⁾	f _{CPU} = 8 MHz	0.40	0.52	0.57	0.66		
	1.8 V to 3.6 V		f _{CPU} = 16 MHz	0.760	1.01	1.05	1.16		
		LSI	f _{CPU} = f _{LSI}	0.035	0.044	0.046	0.054		
			LSE ⁽⁴⁾ external clock (32.768 kHz)	f _{CPU} = f _{LSE}	0.032	0.036	0.038	0.051	
			HSI	f _{CPU} = 125 kHz	0.38	0.48	0.49	0.56	
				f _{CPU} = 1 MHz	0.41	0.49	0.51	0.59	
				f _{CPU} = 4 MHz	0.50	0.57	0.58	0.66	
				f _{CPU} = 8 MHz	0.60	0.66	0.68	0.74	
		CPU not		f _{CPU} = 16 MHz	0.79	0.84	0.86	0.90	
	Supply	clocked, all peripherals		f _{CPU} = 125 kHz	0.06	0.08	0.09	0.12	
I _{DD(Wait)}	current in Wait	OFF, code executed	HSE ⁽³⁾	f _{CPU} = 1 MHz	0.10	0.17	0.18	0.22	mA
	mode	from Flash,	external clock (f _{CPU} =HSE)	f _{CPU} = 4 MHz	0.24	0.36	0.39	0.44	
		V _{DD} from 1.8 V to 3.6 V		f _{CPU} = 8 MHz	0.50	0.58	0.61	0.64	
				f _{CPU} = 16 MHz	1.00	1.08	1.14	1.18	
			LSI	f _{CPU} = f _{LSI}	0.055	0.058	0.065	0.080	
			LSE ⁽⁵⁾ external clock (32.768 kHz)	f _{CPU} = f _{LSE}	0.051	0.056	0.060	0.073	

^{1.} All peripherals OFF, V_{DD} from 1.8 V to 3.6 V, HSI internal RC osc. , f_{CPU} = f_{SYSCLK}

^{3.} Oscillator bypassed (HSEBYP = 1 in CLK_ECKCR). When configured for external crystal, the HSE consumption (I_{DD HSE}) must be added. Refer to *Table 28*.



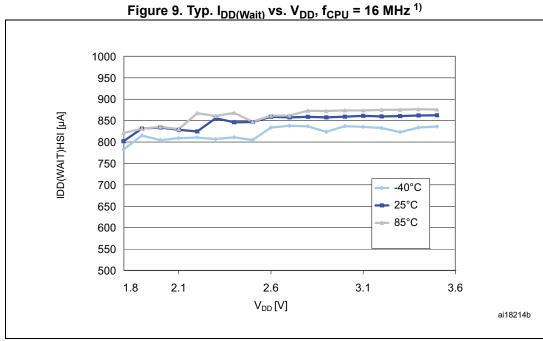
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^{2.} Flash is configured in I_{DDQ} mode in Wait mode by setting the EPM or WAITM bit in the Flash_CR1 register.

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Oscillator bypassed (LSEBYP = 1 in CLK_ECKCR). When configured for external crystal, the LSE consumption ($I_{DD\ HSE}$) must be added. Refer to Table 29.

Oscillator bypassed (LSEBYP = 1 in CLK_ECKCR). When configured for external crystal, the LSE consumption ($I_{DD\ HSE}$) must be added. Refer to *Table 29*.



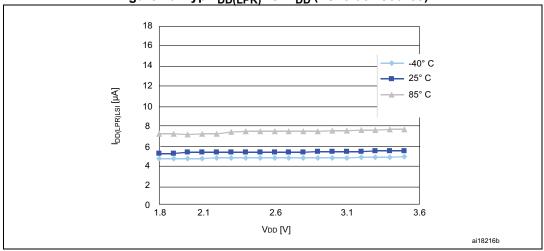
1. Typical current consumption measured with code executed from Flash memory.

Table 19. Total current consumption and timing in Low-power run mode at V_{DD} = 1.8 V to 3.6 V

Symbol	Parameter	u: • <u>b</u>	Conditions ⁽¹⁾		Тур	Max	Unit
				T _A = -40 °C to 25 °C	5.1	5.4	
			all peripherals OFF	T _A = 55 °C	5.7	6	
		all peripricials of t	T _A = 85 °C	6.8	7.5		
	LSI RC osc.		T _A = 125 °C	13.4	16.6		
	(at 38 kHz)		T _A = -40 °C to 25 °C	5.4	5.7		
		with TIM2 active ⁽²⁾	T _A = 55 °C	6.0	6.3		
			WILLI THVIZ ACTIVE	T _A = 85 °C	7.2	7.8	
I _{DD(LPR)}	Supply current in			T _A = 125 °C	13.8	17	μΑ
יטט(נאג)	Low-power run mode		all peripherals OFF	T _A = -40 °C to 25 °C	5.25	5.6	μΛ
				T _A = 55 °C	5.67	6.1	
			all peripricials of t	T _A = 85 °C	5.85	6.3	
		LSE ⁽³⁾ external clock		T _A = 125 °C	9.84	12	
		(32.768 kHz)		$T_A = -40 ^{\circ}\text{C} \text{ to } 25 ^{\circ}\text{C}$	5.59	6	
			with TIM2 active ⁽²⁾	T _A = 55 °C	6.10	6.4	
				T _A = 85 °C	6.30	7	
			T _A = 125 °C	10.1	15		

- 1. No floating I/Os
- 2. Timer 2 clock enabled and counter running
- Oscillator bypassed (LSEBYP = 1 in CLK_ECKCR). When configured for extenal crystal, the LSE consumption (I_{DD LSE}) must be added. Refer to Table 29

Figure 10. Typ. I_{DD(LPR)} vs. V_{DD} (LSI clock source)



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Table 20. Total current consumption in Low-power wait mode at V_{DD} = 1.8 V to 3.6 V

Symbol	Parameter		Conditions ⁽¹⁾		Тур	Max	Unit
				T _A = -40 °C to 25 °C	3	3.3	
			all peripherals OFF	T _A = 55 °C	3.3	3.6	
			all peripricials of t	T _A = 85 °C	4.4	5	
		LSI RC osc. (at 38 kHz)	T _A = 125 °C	11	14		
				$T_A = -40 ^{\circ}\text{C} \text{ to } 25 ^{\circ}\text{C}$	3.4	3.7	
			3.7	4			
	Supply current in Low-power wait mode		With Third active	T _A = 85 °C	4.8	5.4	
I _{DD(LPW)}				T _A = 125 °C	11.3	14.5	μΑ
·DD(LPVV)				$T_A = -40 ^{\circ}\text{C} \text{ to } 25 ^{\circ}\text{C}$	2.35	2.7	
			all peripherals OFF	T _A = 55 °C	2.42	2.82	
		1.05	an peripricials of t	T _A = 85 °C	3.10	3.71	
		LSE external clock ⁽³⁾		T _A = 125 °C	7.20	11	
		(32.768 kHz)		T _A = -40 °C to 25 °C	2.46	2.75	
		(======================================	with TIM2 active (2)	T _A = 55 °C	2.50	2.81	
				T _A = 85 °C	3.16	3.82	
				T _A = 125 °C	7.28	11	

- 1. No floating I/Os.
- 2. Timer 2 clock enabled and counter is running.
- 3. Oscillator bypassed (LSEBYP = 1 in CLK_ECKCR). When configured for extenal crystal, the LSE consumption ($I_{DD\ LSE}$) must be added. Refer to *Table* 29.

Figure 11. Typ. $I_{DD(LPW)}$ vs. V_{DD} (LSI clock source) 16.00 14.00 -40°C 12.00 25°C lpp(LPW)LSI [µA] 10.00 85°C 8.00 6.00 4.00 2.00 0.00 2.1 2.6 1.8 3.1 3.6 VDD [V] ai18217b



Table 21. Total current consumption and timing in Active-halt mode at V_{DD} = 1.8 V to 3.6 V

Symbol	Parameter	Conditions ⁽¹⁾		Тур	Max	Unit
			$T_A = -40 ^{\circ}\text{C} \text{ to } 25 ^{\circ}\text{C}$	0.9	2.1	
	Supply current in Active-halt mode	LSI RC (at 38 kHz)	T _A = 55 °C	1.2	3	
		LOT NO (at 30 KHZ)	T _A = 85 °C	1.5	3.4	
lpp/aux			T _A = 125 °C	5.1	12	
I _{DD(AH)}			$T_A = -40 ^{\circ}\text{C} \text{ to } 25 ^{\circ}\text{C}$	0.5	1.2	μΑ
		(0)	T _A = 55 °C	0.62	1.4	
			T _A = 85 °C	0.88	2.1	
			T _A = 125 °C	4.8	11	
I _{DD(WUFAH)}	Supply current during wakeup time from Active-halt mode (using HSI)	-	-	2.4	1	mA
t _{WU_HSI(AH)} (3)(4)	Wakeup time from Active-halt mode to Run mode (using HSI)	-	-	4.7	7	μs
t _{WU_LSI(AH)} (3) (4)	Wakeup time from Active-halt mode to Run mode (using LSI)	-	-	150	1	μs

^{1.} No floating I/O, unless otherwise specified.

Table 22. Typical current consumption in Active-halt mode, RTC clocked by LSE external crystal

Symbol	Parameter	Condition ⁽¹⁾		Тур	Unit
		\/ -19\/	LSE	1.15	
		V _{DD} = 1.8 V	LSE/32 ⁽³⁾	1.05	
(2)	Supply current in Active-halt	LSE	1.30		
I _{DD(AH)} (2)	mode	V _{DD} = 3 V	LSE/32 ⁽³⁾	1.30	μA
		V _{DD} = 3.6 V	LSE	1.45	
		v _{DD} = 3.0 v	LSE/32 ⁽³⁾	1.35	

^{1.} No floating I/O, unless otherwise specified.

- 2. Based on measurements on bench with 32.768 kHz external crystal oscillator.
- 3. RTC clock is LSE divided by 32.



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Oscillator bypassed (LSEBYP = 1 in CLK_ECKCR). When configured for extenal crystal, the LSE consumption (I_{DD LSE}) must be added. Refer to Table 29.

Wakeup time until start of interrupt vector fetch. The first word of interrupt routine is fetched 4 CPU cycles after t_{WU}.

^{4.} ULP=0 or ULP=1 and FWU=1 in the PWR_CSR2 register.

Electrical parameters STM8L050J3

In the following table, data is based on characterization results, unless otherwise specified.

Table 23. Total current consumption and timing in Halt mode at V_{DD} = 1.8 to 3.6 V

Symbol	Parameter	Condition ⁽¹⁾	Тур	Max	Unit
	Supply current in Halt mode (Ultra-low-power ULP bit =1 in the PWR_CSR2 register)	T _A = -40 °C to 25 °C	350	1400 ⁽²⁾	
I _{DD(Halt)} (Ultra-low-power ULP bit =		T _A = 55 °C	580	2000	nA
		T _A = 85 °C	1160	2800 ⁽²⁾	
		T _A = 125 °C	4.4	13 ⁽²⁾	μA
I _{DD(WUHalt)}	Supply current during wakeup time from Halt mode (using HSI)	-	2.4	-	mA
t _{WU_HSI(Halt)} (3)(4)	Wakeup time from Halt to Run mode (using HSI)	-	4.7	7	μs
t _{WU_LSI(Halt)} (3)(4)	Wakeup time from Halt mode to Run mode (using LSI)	-	150	-	μs

^{1.} T_A = -40 to 125 °C, no floating I/O, unless otherwise specified.

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^{2.} Tested in production.

^{3.} ULP=0 or ULP=1 and FWU=1 in the PWR_CSR2 register.

Wakeup time until start of interrupt vector fetch.
 The first word of interrupt routine is fetched 4 CPU cycles after t_{WU}.

Current consumption of on-chip peripherals

Table 24. Peripheral current consumption

Symbol	Parameter		Typ. V _{DD} = 3.0 V	Unit
I _{DD(TIM2)}	TIM2 supply current (1)		8	
I _{DD(TIM3)}	TIM3 supply current (1)		8	
I _{DD(TIM4)}	TIM4 timer supply current ⁽¹⁾		3	
I _{DD(USART1)}	USART1 supply current (2)		6	μΑ/MHz
I _{DD(SPI1)}	SPI1 supply current (2)	SPI1 supply current (2)		
I _{DD(I2C1)}	I2C1 supply current (2)		5	
I _{DD(DMA1)}	DMA1 supply current ⁽²⁾		3	
I _{DD(WWDG)}	WWDG supply current ⁽²⁾		2	
I _{DD(ALL)}	Peripherals ON ⁽³⁾		44	μΑ/MHz
I _{DD(ADC1)}	ADC1 supply current ⁽⁴⁾		1500	
I _{DD(COMP1)}	Comparator 1 supply current ⁽⁵⁾		0.160	
I _{DD(COMP2)}	Comparator 2 supply current ⁽⁵⁾	Slow mode	2	•
·DD(COMP2)	Comparator 2 supply current	Fast mode	5	
I _{DD(PVD/BOR)}	Power voltage detector and brownout Recurrent ⁽⁶⁾	eset unit supply	2.6	μΑ
I _{DD(BOR)}	Brownout Reset unit supply current (6)		2.4	
I _{DD(IDWDG)}		including LSI supply current	0.45	
(פראסו)סמי	Independent watchdog supply current	excluding LSI supply current	0.05	

Data based on a differential I_{DD} measurement between all peripherals OFF and a timer counter running at 16 MHz. The CPU is in Wait mode in both cases. No IC/OC programmed, no I/O pins toggling. Not tested in production.

- $3. \quad \text{Peripherals listed above the I}_{\text{DD(ALL)}} \text{ parameter ON: TIM1, TIM2, TIM3, TIM4, USART1, SPI1, I2C1, DMA1, WWDG. } \\$
- 4. Data based on a differential I_{DD} measurement between ADC in reset configuration and continuous ADC conversion.
- Data based on a differential IDD measurement between COMP1 or COMP2 in reset configuration and COMP1 or COMP2 enabled with static inputs. Supply current of internal reference voltage excluded.
- 6. Including supply current of internal reference voltage.



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Data based on a differential I_{DD} measurement between the on-chip peripheral in reset configuration and not clocked and the on-chip peripheral when clocked and not kept under reset. The CPU is in Wait mode in both cases. No I/O pins toggling. Not tested in production.

Table 25. Current consumption under external reset

Symbol	Parameter	Conditions		Тур	Unit
	Complete our monte and or	All mines are systems allo	V _{DD} = 1.8 V	48	
I _{DD(RST)}	Supply current under external reset ⁽¹⁾	All pins are externally tied to V _{DD}	V _{DD} = 3 V	76	μΑ
	oxiomal root		V _{DD} = 3.6 V	91	

^{1.} All pins except PA0, PB0 and PB4 are floating under reset. PA0, PB0 and PB4 are configured with pull-up under reset.

8.3.4 Clock and timing characteristics

HSE external clock (HSEBYP = 1 in CLK_ECKCR)

Subject to general operating conditions for V_{DD} and T_A.

Table 26. HSE external clock characteristics

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
f _{HSE_ext}	External clock source frequency ⁽¹⁾	-	1	-	16	MHz
V _{HSEH}	OSC_IN input pin high level voltage	-	0.7 x V _{DD}	-	V _{DD}	V
V _{HSEL}	OSC_IN input pin low level voltage	-	V _{SS}	-	0.3 x V _{DD}	V
C _{in(HSE)}	OSC_IN input capacitance ⁽¹⁾	-	-	2.6	-	pF
I _{LEAK_HSE} OSC_IN input leakage current		$V_{SS} < V_{IN} < V_{DD}$	-	-	±1	μΑ

^{1.} Guaranteed by design.

LSE external clock (LSEBYP=1 in CLK_ECKCR)

Subject to general operating conditions for V_{DD} and T_{A} .

Table 27. LSE external clock characteristics

Symbol	Parameter	Min	Тур	Max	Unit
f _{LSE_ext}	External clock source frequency ⁽¹⁾	-	32.768	-	kHz
V _{LSEH} ⁽²⁾	OSC32_IN input pin high level voltage	0.7 x V _{DD}	-	V_{DD}	V
V _{LSEL} ⁽²⁾	OSC32_IN input pin low level voltage	V _{SS}	-	0.3 x V _{DD}	V
C _{in(LSE)}	OSC32_IN input capacitance ⁽¹⁾	-	0.6	-	pF
I _{LEAK_LSE}	OSC32_IN input leakage current	-	-	±1	μΑ

^{1.} Guaranteed by design.

^{2.} Guaranteed by characterization results.

HSE crystal/ceramic resonator oscillator

The HSE clock can be supplied with a 1 to 16 MHz crystal/ceramic resonator oscillator. All the information given in this paragraph is based on characterization results with specified typical external components. In the application, the resonator and the load capacitors have to be placed as close as possible to the oscillator pins in order to minimize output distortion and startup stabilization time. Refer to the crystal resonator manufacturer for more details (frequency, package, accuracy...).

Symbol	Parameter	Conditions	Min	Тур	Max	Unit			
f _{HSE}	High speed external oscillator frequency	-	1	-	16	MHz			
R _F	Feedback resistor	-	-	200	-	kΩ			
C ⁽¹⁾	Recommended load capacitance (2)	-	-	20	-	pF			
	HSE oscillator power consumption	C = 20 pF, f _{OSC} = 16 MHz	-	-	2.5 (startup) 0.7 (stabilized) ⁽³⁾	mA			
IDD(HSE)		C = 10 pF, f _{OSC} =16 MHz	-	-	2.5 (startup) 0.46 (stabilized) ⁽³⁾	IIIA			
9 _m	Oscillator transconductance	-	3.5 ⁽³⁾	-	-	mA/V			
t _{SU(HSE)} ⁽⁴⁾	Startup time	V _{DD} is stabilized	-	1	-	ms			

Table 28. HSE oscillator characteristics

- 1. $C=C_{L1}=C_{L2}$ is approximately equivalent to 2 x crystal C_{LOAD} .
- The oscillator selection can be optimized in terms of supply current using a high quality resonator with small $R_{\rm m}$ value. Refer to crystal manufacturer for more details
- 3. Guaranteed by design.
- t_{SU(HSE)} is the startup time measured from the moment it is enabled (by software) to a stabilized 16 MHz oscillation. This is measured for a standard crystal resonator and it can vary significantly with the crystal manufacturer.

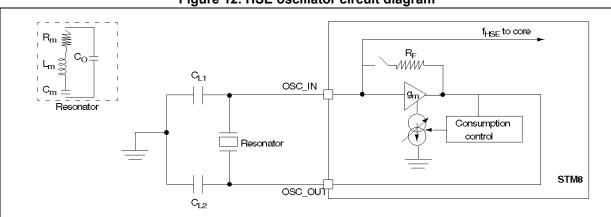


Figure 12. HSE oscillator circuit diagram

HSE oscillator critical g_m formula

$$g_{mcrit} = (2 \times \Pi \times f_{HSE})^2 \times R_m (2Co + C)^2$$

R_m: Motional resistance (see crystal specification), L_m: Motional inductance (see crystal specification), C_m: Motional capacitance (see crystal specification), Co: Shunt capacitance (see crystal specification),

 C_{L1} = C_{L2} =C: Grounded external capacitance $g_m >> g_{morit}$

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LSE crystal/ceramic resonator oscillator

The LSE clock can be supplied with a 32.768 kHz crystal/ceramic resonator oscillator. All the information given in this paragraph is based on characterization results with specified typical external components. In the application, the resonator and the load capacitors have to be placed as close as possible to the oscillator pins in order to minimize output distortion and startup stabilization time. Refer to the crystal resonator manufacturer for more details (frequency, package, accuracy...).

	Table 23. Lot	- Oscillator Chara	Cicilistic	<u> </u>	Table 23. LOC Oscillator characteristics									
Symbol	Parameter	Conditions	Min	Тур	Max	Unit								
f _{LSE}	Low speed external oscillator frequency	-	-	32.768	-	kHz								
R _F	Feedback resistor	ΔV = 200 mV	-	1.2	-	МΩ								
C ⁽¹⁾	Recommended load capacitance (2)	-	-	8	-	pF								
		-	-	-	1.4 ⁽³⁾	μΑ								
1 .		V _{DD} = 1.8 V	-	450	-									
I _{DD(LSE)}	LSE oscillator power consumption	V _{DD} = 3 V	-	600	-	nA								
		V _{DD} = 3.6 V	-	750	-									
9 _m	Oscillator transconductance	-	3 ⁽³⁾	-	-	μA/V								
t _{SU(LSE)} ⁽⁴⁾	Startup time	V _{DD} is stabilized	-	1	-	s								

Table 29. LSE oscillator characteristics

t_{SU(LSE)} is the startup time measured from the moment it is enabled (by software) to a stabilized 32.768 kHz oscillation. This value is measured for a standard crystal resonator and it can vary significantly with the crystal manufacturer.

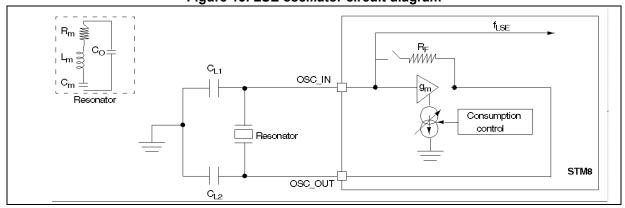


Figure 13. LSE oscillator circuit diagram

^{1.} C=C_{L1}=C_{L2} is approximately equivalent to 2 x crystal C_{LOAD}.

The oscillator selection can be optimized in terms of supply current using a high quality resonator with a small R_m value. Refer to crystal manufacturer for more details.

^{3.} Guaranteed by design.

Internal clock sources

Subject to general operating conditions for V_{DD}, and T_A.

High speed internal RC oscillator (HSI)

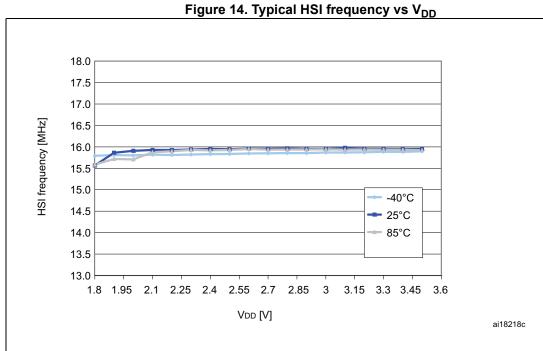
In the following table, data is based on characterization results, not tested in production, unless otherwise specified.

Table 30. HSI oscillator characteristics

Symbol	Parameter	Conditions ⁽¹⁾	Min	Тур	Max	Unit
f _{HSI}	Frequency	V _{DD} = 3.0 V	-	16	-	MHz
	Accuracy of HSI oscillator (factory calibrated)	V _{DD} = 3.0 V, T _A = 25 °C	-2.5	-	2.5	%
ACC _{HSI}		1.8 V ≤ V _{DD} ≤ 3.6 V, -40 °C ≤ T _A ≤ 125 °C	-5	-	5	%
TRIM	HSI user trimming step ⁽²⁾	Trimming code ≠ multiple of 16	-	0.4	0.7	%
I IXIIVI		Trimming code = multiple of 16	-	-	± 1.5	%
t _{su(HSI)}	HSI oscillator setup time (wakeup time)	-	-	3.7	6 ⁽³⁾	μs
I _{DD(HSI)}	HSI oscillator power consumption	-	-	100	140 ⁽³⁾	μА

^{1.} V_{DD} = 3.0 V, T_A = -40 to 125 °C unless otherwise specified.

3. Guaranteed by design.



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^{2.} The trimming step differs depending on the trimming code. It is usually negative on the codes which are multiples of 16 (0x00, 0x10, 0x20, 0x30...0xE0). Refer to the AN3101 "STM8L15x internal RC oscillator calibration" application note for more details.

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Low speed internal RC oscillator (LSI)

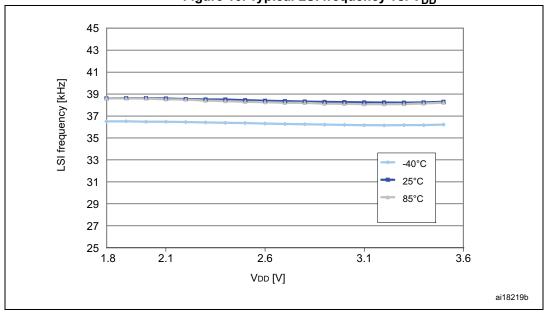
In the following table, data is based on characterization results, not tested in production.

Table 31. LSI oscillator characteristics

Symbol	Parameter ⁽¹⁾	Parameter ⁽¹⁾ Conditions ⁽¹⁾		Тур	Max	Unit
f _{LSI}	Frequency	-	26	38	56	kHz
t _{su(LSI)}	LSI oscillator wakeup time	-	-	-	200 ⁽²⁾	μs
I _{DD(LSI)}	LSI oscillator frequency drift ⁽³⁾	0 °C ≤T _A ≤85 °C	-12	-	11	%

- 1. V_{DD} = 1.8 V to 3.6 V, T_A = -40 to 125 °C unless otherwise specified.
- 2. Guaranteed by design.
- 3. This is a deviation for an individual part, once the initial frequency has been measured.

Figure 15. Typical LSI frequency vs. V_{DD}



8.3.5 Memory characteristics

 T_A = -40 to 125 °C unless otherwise specified.

Table 32. RAM and hardware registers

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
V_{RM}	Data retention mode (1)	Halt mode (or Reset)	1.8	-	-	V

Minimum supply voltage without losing data stored in RAM (in Halt mode or under Reset) or in hardware registers (only in Halt mode). Guaranteed by characterization.

Flash memory

Table 33. Flash program and data EEPROM memory

Symbol	Parameter	Conditions	Min	Тур	Max (1)	Unit
V _{DD}	Operating voltage (all modes, read/write/erase)	f _{SYSCLK} = 16 MHz	1.8	-	3.6	V
	Programming time for 1 or 64 bytes (block) erase/write cycles (on programmed byte)	-	-	6	-	ms
t _{prog}	Programming time for 1 to 64 bytes (block) write cycles (on erased byte)	-	-	3	-	ms
	Programming/ erasing consumption	T _A =+25 °C, V _{DD} = 3.0 V	-	0.7	-	mA
^I prog	Trogramming, crasing consumption	T _A =+25 °C, V _{DD} = 1.8 V	-	0.7	-	IIIA
	Data retention (program memory) after 100 erase/write cycles at T _A = -40 to +85 °C	T _{RET} = +85 °C	30 ⁽¹⁾	-	-	
t _{RET} ⁽²⁾	Data retention (program memory) after 1000 erase/write cycles at T _A = -40 to +125 °C	T _{RET} = +125 °C	5 ⁽¹⁾	-	-	years
RET`	Data retention (data memory) after 100000 erase/write cycles at T _A = –40 to +85 °C	T _{RET} = +85 °C	30 ⁽¹⁾	-	-	
	Data retention (data memory) after 300000 erase/write cycles at T _A = –40 to +125 °C	T _{RET} = +125 °C	5 ⁽¹⁾	-	-	-
	Erase/write cycles (program memory)		100 ⁽¹⁾	-	-	cycles
N _{RW} ⁽³⁾	Erase/write cycles (data memory)	$T_A = -40 \text{ to } +85 ^{\circ}\text{C}$	100 ⁽¹⁾	-	-	kcycles

^{1.} Guaranteed by characterization results.

4. Data based on characterization performed on the whole data memory.



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^{2.} Conforming to JEDEC JESD22a117

The physical granularity of the memory is 4 bytes, so cycling is performed on 4 bytes even when a write/erase operation addresses a single byte.

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8.3.6 I/O current injection characteristics

As a general rule, current injection to the I/O pins, due to external voltage below V_{SS} or above V_{DD} (for standard pins) should be avoided during normal product operation. However, in order to give an indication of the robustness of the microcontroller in cases when abnormal injection accidentally happens, susceptibility tests are performed on a sample basis during device characterization.

Functional susceptibilty to I/O current injection

While a simple application is executed on the device, the device is stressed by injecting current into the I/O pins programmed in floating input mode. While current is injected into the I/O pin, one at a time, the device is checked for functional failures.

The failure is indicated by an out of range parameter: ADC error, out of spec current injection on adjacent pins or other functional failure (for example reset, oscillator frequency deviation, LCD levels, etc.).

The test results are given in the following table.

Functional susceptibility Unit **Symbol** Description **Positive** Negative injection injection Injected current on any other pin -5 +5 mA

Table 34. I/O current injection susceptibility

8.3.7 I/O port pin characteristics

 I_{INJ}

General characteristics

Subject to general operating conditions for V_{DD} and T_A unless otherwise specified. All unused pins must be kept at a fixed voltage: using the output mode of the I/O for example or an external pull-up or pull-down resistor.

Table 35. I/O static characteristics

Symbol	Parameter	Conditions ⁽¹⁾	Min	Тур	Max	Unit	
V _{IL}	Input low level voltage ⁽²⁾	Input voltage on true open-drain pins (PC0 and PC1)	V _{SS} -0.3	-	0.3 x V _{DD}	V	
		Input voltage on any other pin	V _{SS} -0.3	-	0.3 x V _{DD}		
V_{IH}	Input high level voltage (2)	Input voltage on any other pin	0.70 x V _{DD}	-	V _{DD} +0.3	٧	
V _{hys}	Schmitt trigger voltage hysteresis ⁽³⁾	I/Os	-	200	-	mV	
		True open drain I/Os	-	200 -		1110	
	Input leakage current ⁽⁴⁾	$V_{SS} \le V_{IN} \le V_{DD}$ High sink I/Os	-	-	50 ⁽⁵⁾		
I _{lkg}		$V_{SS} \le V_{IN} \le V_{DD}$ True open drain I/Os	-	-	200 ⁽⁵⁾	nA	
g		$V_{SS} \le V_{IN} \le V_{DD}$ PA0 with high sink LED driver capability	-	-	200 ⁽⁵⁾		
R _{PU}	Weak pull-up equivalent resistor ⁽²⁾⁽⁶⁾	V _{IN} = V _{SS}	30	45	60	kΩ	
C _{IO}	I/O pin capacitance	-	-	5 ⁽⁷⁾	-	pF	

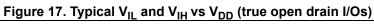
- 1. V_{DD} = 3.0 V, T_A = -40 to 125 °C unless otherwise specified.
- 2. Guaranteed by characterization results.
- 3. Hysteresis voltage between Schmitt trigger switching levels. Based on characterization results, not tested.
- 4. The max. value may be exceeded if negative current is injected on adjacent pins.
- 5. Not tested in production.
- R_{PU} pull-up equivalent resistor based on a resistive transistor (corresponding I_{PU} current characteristics described in Figure 19).
- 7. Capacitance per one GPIO on pin. Complete pin capacitance depends on how many GPIOs are connected on a given pin (see *Table 4*). The total pin capacitance is then N x C_{IO} where N = number of GPIOs on a given pin).

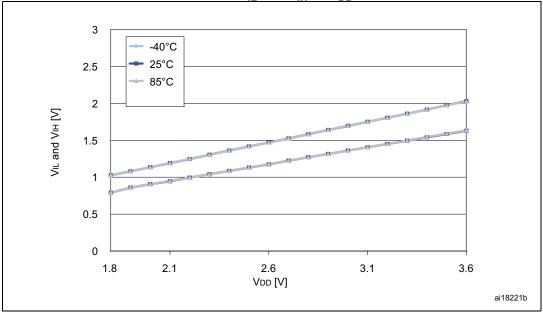


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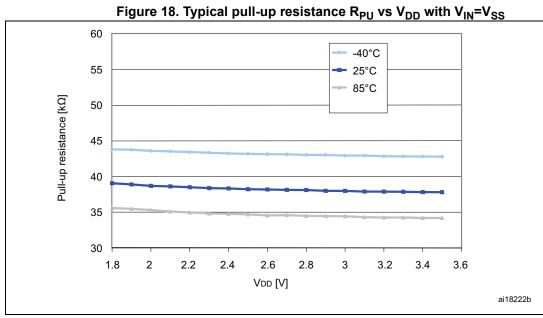
3 -40°C 25°C 2.5 -- 85°C 2 Vi∟ and Viн [V] 1.5 0.5 0 2.1 2.6 1.8 3.1 3.6 VDD [V] ai18220c

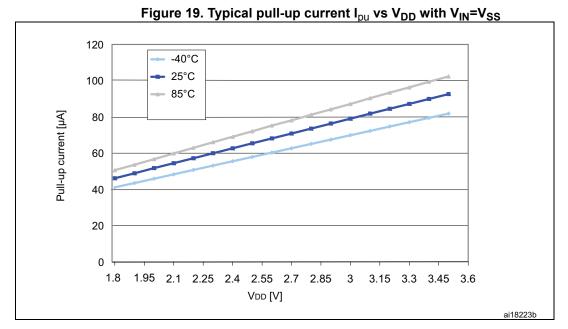
Figure 16. Typical V_{IL} and V_{IH} vs V_{DD} (high sink I/Os)





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Output driving current

Subject to general operating conditions for V_{DD} and T_{A} unless otherwise specified.

Table 36. Output driving current (high sink ports)

I/O Type	Symbol	Parameter	Conditions	Min	Max	Unit
	V _{OL} ⁽¹⁾	Output low level voltage for an I/O pin	I _{IO} = +2 mA, V _{DD} = 3.0 V	-	0.45	٧
			I_{IO} = +2 mA, V_{DD} = 1.8 V	1	0.45	>
High sink			I _{IO} = +10 mA, V _{DD} = 3.0 V	-	0.7	>
High	V _{OH} ⁽²⁾	Output high level voltage for an I/O pin	I_{IO} = -2 mA, V_{DD} = 3.0 V	V _{DD} -0.45	-	٧
			I _{IO} = -1 mA, V _{DD} = 1.8 V	V _{DD} -0.45	-	>
			I _{IO} = -10 mA, V _{DD} = 3.0 V	V _{DD} -0.7	-	>

The I_{IO} current sunk must always respect the absolute maximum rating specified in *Table 13: Current characteristics* and the sum of I_{IO} (I/O ports and control pins) must not exceed I_{VSS}.

Table 37. Output driving current (true open drain ports)

I/O Type	Symbol	Parameter	Conditions	Min	Max	Unit
drain	V (1)	Output love love love the rea few are 1/O min	I_{IO} = +3 mA, V_{DD} = 3.0 V	-	0.45	V
Open drain	V _{OL} ⁽¹⁾ Output	Output low level voltage for an I/O pin	I _{IO} = +1 mA, V _{DD} = 1.8 V	-	0.45	V

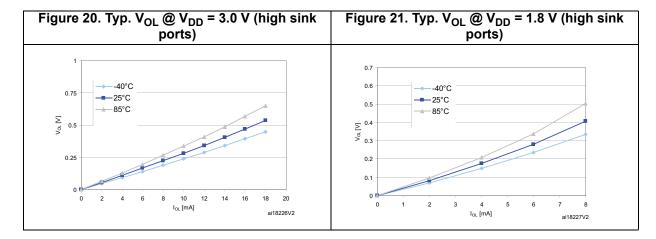
The I_{IO} current sunk must always respect the absolute maximum rating specified in Table 13: Current characteristics and the sum of I_{IO} (I/O ports and control pins) must not exceed I_{VSS}.

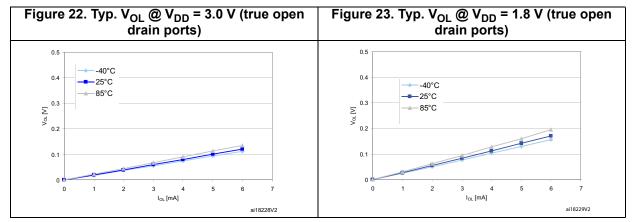
Table 38. Output driving current (PA0 with high sink LED driver capability)

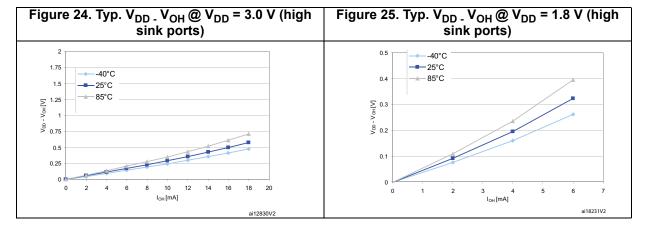
I/O Type	Symbol	Parameter	Conditions	Min	Max	Unit
∝	V _{OL} ⁽¹⁾	Output low level voltage for an I/O pin	I _{IO} = +20 mA, V _{DD} = 2.0 V	-	0.45	V

The I_{IO} current sunk must always respect the absolute maximum rating specified in Table 13: Current characteristics and the sum of I_{IO} (I/O ports and control pins) must not exceed I_{VSS}.

^{2.} The I_{IO} current sourced must always respect the absolute maximum rating specified in *Table 13: Current characteristics* and the sum of I_{IO} (I/O ports and control pins) must not exceed I_{VDD} .







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8.3.8 Communication interfaces

SPI1 - Serial peripheral interface

Unless otherwise specified, the parameters given in *Table 39* are derived from tests performed under ambient temperature, f_{SYSCLK} frequency and V_{DD} supply voltage conditions summarized in *Section 8.3.1*. Refer to I/O port characteristics for more details on the input/output alternate function characteristics (NSS, SCK, MOSI, MISO).

Table 39. SPI1 characteristics

Symbol	Parameter	Conditions ⁽¹⁾	Min	Max	Unit
f _{SCK}	SPI1 clock frequency	Master mode	0	8	
1/t _{c(SCK)}	SFTT Clock frequency	Slave mode	0	8	MHz
$t_{r(SCK)} \ t_{f(SCK)}$	SPI1 clock rise and fall time	Capacitive load: C = 30 pF	-	30	
t _{su(NSS)} ⁽²⁾	NSS setup time	Slave mode	4 x 1/f _{SYSCLK}	-	
t _{h(NSS)} ⁽²⁾	NSS hold time	Slave mode	80	-	
t _{w(SCKH)} (2) t _{w(SCKL)} (2)	SCK high and low time	Master mode, f _{MASTER} = 8 MHz, f _{SCK} = 4 MHz	105	145	
$t_{\text{su(MI)}}^{(2)} \\ t_{\text{su(SI)}}^{(2)}$	Data input setup time	Master mode	30	-	
t _{su(SI)} (2)	Data input setup time	Slave mode	3	-	
t _{h(MI)} (2) t _{h(SI)} (2)	Data input hold time	Master mode	15	-	ns
	Data input noid time	Slave mode	0	-	113
t _{a(SO)} (2)(3)	Data output access time	Slave mode	-	3x 1/f _{SYSCLK}	
t _{dis(SO)} (2)(4)	Data output disable time	Slave mode	30	-	
t _{v(SO)} (2)	Data output valid time	Slave mode (after enable edge)	-	60	
t _{v(MO)} ⁽²⁾	Data output valid time	Master mode (after enable edge)	-	20	
t _{h(SO)} (2)		Slave mode (after enable edge)	15	-	
t _{h(MO)} ⁽²⁾	Data output hold time	Master mode (after enable edge)	1	-	

^{1.} Parameters are given by selecting 10 MHz I/O output frequency.



^{2.} Values based on design simulation and/or characterization results, and not tested in production.

^{3.} Min time is for the minimum time to drive the output and max time is for the maximum time to validate the data.

^{4.} Min time is for the minimum time to invalidate the output and max time is for the maximum time to put the data in Hi-Z.

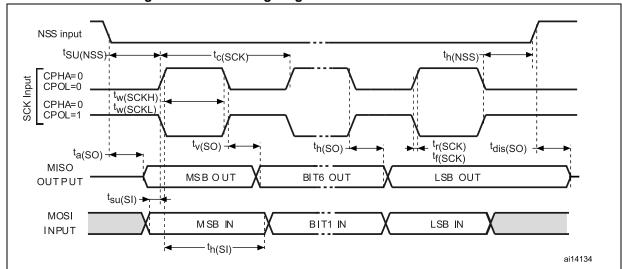
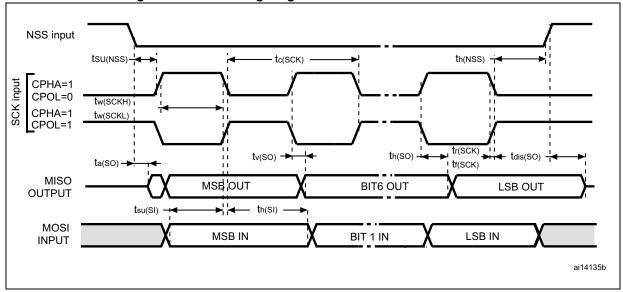


Figure 26. SPI1 timing diagram - slave mode and CPHA=0





1. Measurement points are done at CMOS levels: $0.3V_{DD}$ and $0.7V_{DD}$.

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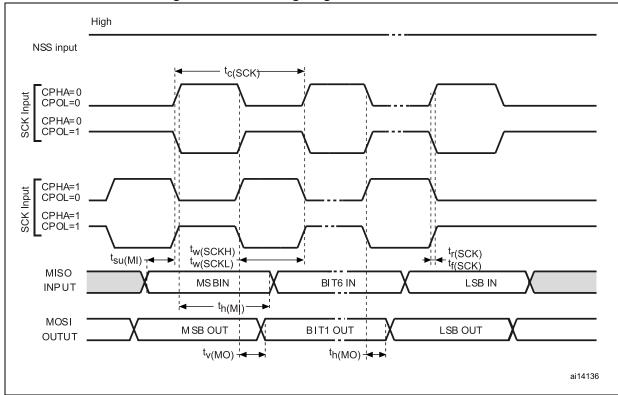


Figure 28. SPI1 timing diagram - master mode⁽¹⁾

1. Measurement points are done at CMOS levels: $0.3V_{DD}$ and $0.7V_{DD}$.

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I2C - Inter IC control interface

Subject to general operating conditions for V_{DD} , f_{SYSCLK} , and T_A unless otherwise specified.

The STM8L I2C interface (I2C1) meets the requirements of the Standard I2C communication protocol described in the following table with the restriction mentioned below:

Refer to I/O port characteristics for more details on the input/output alternate function characteristics (SDA and SCL).

Table 40. I2C characteristics

Symbol	Parameter		rd mode C	Fast mo	de I2C ⁽¹⁾	Unit
		Min ⁽²⁾	Max ⁽²⁾	Min ⁽²⁾	Max ⁽²⁾	
t _{w(SCLL)}	SCL clock low time	4.7	-	1.3	-	0
t _{w(SCLH)}	SCL clock high time	4.0	-	0.6	-	μs
t _{su(SDA)}	SDA setup time	250	-	100	-	
t _{h(SDA)}	SDA data hold time	0	-	0	900	
t _{r(SDA)} t _{r(SCL)}	SDA and SCL rise time	-	1000	-	300	ns
t _{f(SDA)}	SDA and SCL fall time	-	300	-	300	
t _{h(STA)}	START condition hold time	4.0	-	0.6	-	
t _{su(STA)}	Repeated START condition setup time	4.7	-	0.6	-	μs
t _{su(STO)}	STOP condition setup time	4.0	-	0.6	-	μs
t _{w(STO:STA)}	STOP to START condition time (bus free)	4.7	-	1.3	-	μs
C _b	Capacitive load for each bus line	-	400	-	400	pF

^{1.} f_{SYSCLK} must be at least equal to 8 MHz to achieve max fast I2C speed (400 kHz).

Note:

For speeds around 200 kHz, the achieved speed can have a \pm 5% tolerance For other speed ranges, the achieved speed can have a \pm 2% tolerance The above variations depend on the accuracy of the external components used.



^{2.} Data based on standard I2C protocol requirement, not tested in production.

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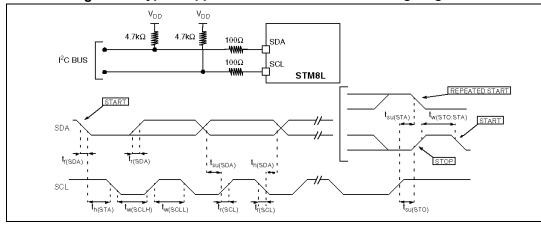


Figure 29. Typical application with I2C bus and timing diagram 1)

1. Measurement points are done at CMOS levels: 0.3 x $\rm V_{DD}$ and 0.7 x $\rm V_{DD}$



8.3.9 Embedded reference voltage

In the following table, data is based on characterization results, not tested in production, unless otherwise specified.

Table 41. Reference voltage characteristics

Symbol	Parameter	Conditions	Min	Тур	Max.	Unit
I _{REFINT}	Internal reference voltage consumption	-	-	1.4	-	μΑ
T _{S_VREFINT} (1)(2)	ADC sampling time when reading the internal reference voltage	-	-	5	10	μs
I _{BUF} ⁽²⁾	Internal reference voltage buffer consumption (used for ADC)	-	-	13.5	25	μΑ
V _{REFINT out}	Reference voltage output	-	1.202 ⁽³⁾	1.224	1.242 ⁽³⁾	V
I _{LPBUF} ⁽²⁾	Internal reference voltage low- power buffer consumption (used for comparator or output)	-	-	730	1200	nA
I _{REFOUT} ⁽²⁾	Buffer output current ⁽⁴⁾	-	-	-	1	μΑ
C _{REFOUT}	Reference voltage output load	-	-	-	50	pF
t _{VREFINT}	Internal reference voltage startup time	-	-	2	3	ms
t _{BUFEN} (2)	Internal reference voltage buffer startup time once enabled ⁽¹⁾	-	-	-	10	μs
ACC _{VREFINT}	Accuracy of V _{REFINT} stored in the VREFINT_Factory_CONV byte ⁽⁵⁾	-	-	ı	± 5	mV
STAR	Stability of V _{REFINT} over temperature	-40 °C ≤ T _A ≤ 125 °C	-	20	50	ppm/°C
STAB _{VREFINT}	Stability of V _{REFINT} over temperature	0 °C ≤ T _A ≤50 °C	-	-	20	ppm/°C
STAB _{VREFINT}	Stability of V _{REFINT} after 1000 hours	-	-	-	TBD	ppm

^{1.} Defined when ADC output reaches its final value $\pm 1/2$ LSB

8.3.10 Comparator characteristics

In the following table, data is guaranteed by design, not tested in production, unless otherwise specified.



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^{2.} Data guaranteed by design.

^{3.} Tested in production at V_{DD} = 3 V ±10 mV.

^{4.} To guaranty less than 1% $V_{\mbox{\scriptsize REFOUT}}$ deviation.

^{5.} Measured at V_{DD} = 3 V ±10 mV. This value takes into account V_{DD} accuracy and ADC conversion accuracy.

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Table 42. Comparator 1 characteristics

Symbol	Parameter	Min	Тур	Max ⁽¹⁾	Unit	
V_{DDA}	Analog supply voltage	1.65	-	3.6	V	
T _A	Temperature range	-40	-	125	° C	
R _{400K}	R _{400K} value	300	400	500	kΩ	
R _{10K}	R _{10K} value	7.5	10	12.5	KΩ	
V _{IN}	Comparator 1 input voltage range	0.6	-	V_{DDA}	V	
V _{REFINT}	Internal reference voltage ⁽²⁾	1.202	1.224	1.242	V	
t _{START}	Comparator startup time	-	7	10	110	
t _d	Propagation delay ⁽³⁾	-	3	10	μs	
V _{offset}	Comparator offset error	-	±3	±10	mV	
I _{COMP1}	Current consumption ⁽⁴⁾	-	160	260	nA	

- 1. Guaranteed by characterization results.
- 2. Tested in production at VDD = $3 \text{ V} \pm 10 \text{ mV}$.
- The delay is characterized for 100 mV input step with 10 mV overdrive on the inverting input, the non-inverting input set to the reference.
- 4. Comparator consumption only. Internal reference voltage not included.

Table 43. Comparator 2 characteristics

Symbol	Parameter	Conditions	Min	Тур	Max ⁽¹⁾	Unit
V_{DDA}	Analog supply voltage	-	1.65	-	3.6	V
T _A	Temperature range	-	-40	-	125	° C
V _{IN}	Comparator 2 input voltage range	-	0	-	V_{DDA}	V
+ .	Comparator startup time	Fast mode	-	15	20	
t _{START}	Comparator startup time	Slow mode	-	20	20	
1	Propagation delay in slow mode ⁽²⁾	1.65 V ≤ V _{DDA} ≤ 2.7 V	-	1.8	3.5	
t _{d slow}		2.7 V ≤ V _{DDA} ≤ 3.6 V	-	2.5	6	μs
+		1.65 V ≤ V _{DDA} ≤ 2.7 V	-	0.8	2	
t _{d fast}	Propagation delay in fast mode ⁽²⁾	$2.7 \text{ V} \leq \text{V}_{DDA}$ $\leq 3.6 \text{ V}$	- 1.2 4			
V _{offset}	Comparator offset error		-	±4	±20	mV
1	Current consumption(3)	Fast mode	-	3.5	5	пΔ
I _{COMP2}	Current consumption ⁽³⁾	Slow mode	-	0.5	2	μΑ

^{1.} Guaranteed by characterization results.

3. Comparator consumption only. Internal reference voltage not included.



The delay is characterized for 100 mV input step with 10 mV overdrive on the inverting input, the non-inverting input set to the reference.

8.3.11 12-bit ADC1 characteristics

In the following table, data is guaranteed by design, not tested in production.

Table 44. ADC1 characteristics

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
V_{DDA}	Analog supply voltage		1.8	-	3.6	V
V	Reference supply	$2.4 \text{ V} \le \text{V}_{DDA} \le 3.6 \text{ V}$	2.4	-	V_{DDA}	V
V _{REF+}	voltage	1.8 V ≤ V _{DDA} ≤ 2.4 V		V_{DDA}		V
V _{REF-}	Lower reference voltage	-		V_{SSA}		V
I _{VDDA}	Current on the VDDA input pin	-	-	1000	1450	μΑ
I _{VREF+}	Current on the VREF+	-	-	400	700 (peak) ⁽¹⁾	μΑ
'VREF+	input pin	-	-	400	450 (average) ⁽¹⁾	μΑ
V _{AIN}	Conversion voltage range	-	0 ⁽²⁾	-	V _{REF+}	-
T _A	Temperature range	-	-40	-	125	°C
R _{AIN}	External resistance on V _{AIN}	on other channels	-	-	50 ⁽³⁾	kΩ
C _{ADC}	Internal sample and hold capacitor	on other channels	-	16	-	pF
f _{ADC}	ADC sampling clock	$2.4 \text{ V} \le \text{V}_{DDA} \le 3.6 \text{ V}$ without zooming	0.320	-	16	MHz
ADC	frequency	$1.8 \text{ V} \leq \text{V}_{DDA} \leq 2.4 \text{ V}$ with zooming	0.320	-	8	MHz
f _{CONV}	12-bit conversion rate	V _{AIN} on all other channels	-	-	760	kHz
f _{TRIG}	External trigger frequency	-	-	-	t _{conv}	1/f _{ADC}
t _{LAT}	External trigger latency	-	-	-	3.5	1/f _{SYSCLK}
to	Sampling time	V _{AIN} on channels V _{DDA} < 2.4 V	0.86	-	-	μs
t _S	Sampling time	V_{AIN} on channels 2.4 V \leq $V_{DDA} \leq$ 3.6 V	0.41	-	-	μs
t	12-bit conversion time	-	12 + t _S		1/f _{ADC}	
t _{conv}	12 bit conversion time	16 MHz		1		μs
t _{WKUP}	Wakeup time from OFF state	-	-	-	3	μs



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Table 44. ADC1 characteristics (continued)

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
t _{IDLE}	Time before a new conversion	-	-	-	8	ms
t _{VREFINT}	Internal reference voltage startup time	-	-	-	refer to Table 41	ms

- 2. $V_{\text{REF-}}$ or V_{SSA} must be tied to ground.
- 3. Guaranteed by design.



^{1.} The current consumption through V_{REF} is composed of two parameters:
- one constant (max 300 μ A)
- one variable (max 400 μ A), only during sampling time + 2 first conversion pulses.
So, peak consumption is 300+400 = 700 μ A and average consumption is 300 + [(4 sampling + 2) /16] x 400 = 450 μ A at 1Msps

In the following three tables, data is guaranteed by characterization result, not tested in production.

Table 45. ADC1 accuracy with V_{DDA} = 3.3 V to 2.5 V

Symbol	Parameter	Conditions	Тур	Max	Unit
		f _{ADC} = 16 MHz	1	1.6	
DNL	Differential non linearity	f _{ADC} = 8 MHz	1	1.6	
		f _{ADC} = 4 MHz	1	1.5	
		f _{ADC} = 16 MHz	1.2	2	
INL	Integral non linearity	f _{ADC} = 8 MHz	1.2	1.8	LSB
		f _{ADC} = 4 MHz	1.2	1.7	
	Total unadjusted error	f _{ADC} = 16 MHz	2.2	3.0	
TUE		f _{ADC} = 8 MHz	1.8	2.5	
		f _{ADC} = 4 MHz	1.8	2.3	
		f _{ADC} = 16 MHz	1.5	2	
Offset	Offset error	f _{ADC} = 8 MHz	1	1.5	
		f _{ADC} = 4 MHz	0.7	1.2	LSB
		f _{ADC} = 16 MHz			LOD
Gain	Gain error	f _{ADC} = 8 MHz	1	1.5	
		f _{ADC} = 4 MHz			

Table 46. ADC1 accuracy with V_{DDA} = 2.4 V to 3.6 V

Symbol	Parameter	Тур	Max	Unit
DNL	Differential non linearity	1	2	LSB
INL	Integral non linearity	1.7	3	LSB
TUE	Total unadjusted error	2	4	LSB
Offset	Offset error	1	2	LSB
Gain	Gain error	1.5	3	LSB

Table 47. ADC1 accuracy with $V_{DDA} = V_{REF+} = 1.8 \text{ V}$ to 2.4 V

Symbol	Parameter	Тур	Max	Unit
DNL	Differential non linearity	1	2	LSB
INL	Integral non linearity	2	3	LSB
TUE	Total unadjusted error	3	5	LSB
Offset	Offset error	2	3	LSB
Gain	Gain error	2	3	LSB



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Electrical parameters STM8L050J3

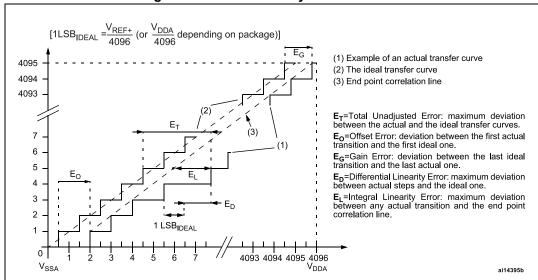
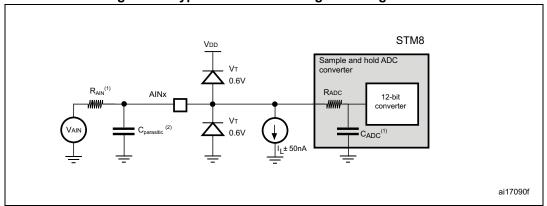


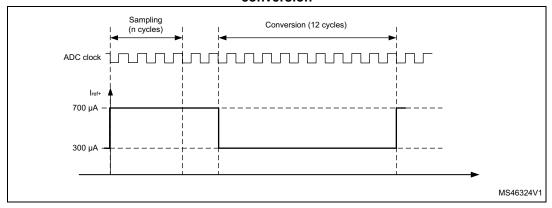
Figure 30. ADC1 accuracy characteristics

Figure 31. Typical connection diagram using the ADC



- Refer to Table 48 for the values of R_{AIN} and C_{ADC}.
- C_{parasitic} represents the capacitance of the PCB (dependent on soldering and PCB layout quality) plus the pad capacitance (roughly 7 pF). A high C_{parasitic} value will downgrade conversion accuracy. To remedy this, f_{ADC} should be reduced.

Figure 32. Maximum dynamic current consumption on V_{REF+} supply pin during ADC conversion



		R _{AIN} ma	x (kohm)
Ts (cycles)	Ts (µs)	Slow cl	hannels
	,	2.4 V < V _{DDA} < 3.6 V	1.8 V < V _{DDA} < 2.4 V
4	0.25	Not allowed	Not allowed
9	0.5625	0.8	Not allowed
16	1	2.0	0.8
24	1.5	3.0	1.8
48	3	6.8	4.0
96	6	15.0	10.0
192	12	32.0	25.0
384	24	50.0	50.0

Table 48. R_{AIN} max for $f_{ADC} = 16 \text{ MHz}^{(1)}$

General PCB design guidelines

Power supply decoupling should be performed as shown in *Figure 33*. Good quality ceramic 10 nF capacitors should be used. They should be placed as close as possible to the chip.

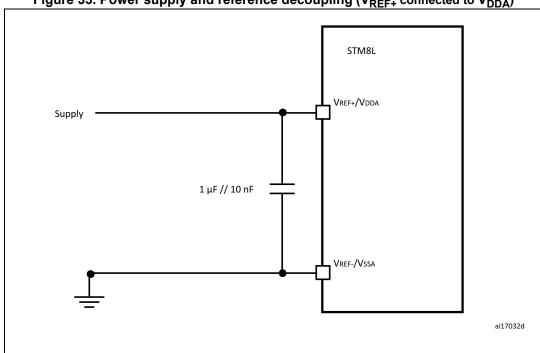


Figure 33. Power supply and reference decoupling (V_{REF+} connected to V_{DDA})

^{1.} Guaranteed by design.

8.3.12 **EMC** characteristics

Susceptibility tests are performed on a sample basis during product characterization.

Functional EMS (electromagnetic susceptibility)

Based on a simple running application on the product (toggling 2 LEDs through I/O ports), the product is stressed by two electromagnetic events until a failure occurs (indicated by the LEDs).

- ESD: Electrostatic discharge (positive and negative) is applied on all pins of the device until a functional disturbance occurs. This test conforms with the IEC 61000 standard.
- FTB: A burst of fast transient voltage (positive and negative) is applied to V_{DD} and V_{SS} through a 100 pF capacitor, until a functional disturbance occurs. This test conforms with the IEC 61000 standard.

A device reset allows normal operations to be resumed. The test results are given in the table below based on the EMS levels and classes defined in application note AN1709.

Designing hardened software to avoid noise problems

EMC characterization and optimization are performed at component level with a typical application environment and simplified MCU software. It should be noted that good EMC performance is highly dependent on the user application and the software in particular.

Therefore it is recommended that the user applies EMC software optimization and prequalification tests in relation with the EMC level requested for his application.

Pregualification trials

To complete these trials, ESD stress can be applied directly on the device, over the range of specification values. When unexpected behavior is detected, the software can be hardened to prevent unrecoverable errors occurring (see application note AN1015).

Symbol	Parameter	Conditions		
V _{FESD}	Voltage limits to be applied on any I/O pin to induce a functional disturbance	V_{DD} = 3.3 V, T_{A} = +25 °C, f_{CPU} = 16 MHz, conforms to IEC 61000		TBD
	Fast transient voltage burst limits	V _{DD} = 3.3 V, T _A = +25 °C,	Using HSI	TBD
V _{EFTB}	V _{EFTB} to be applied through 100 pF on V _{DD} and V _{SS} pins to induce a	f _{CPU} = 16 MHz, conforms to IEC 61000	Using HSE	TBD

Table 49. EMS data

Electromagnetic interference (EMI)

Based on a simple application running on the product (toggling 2 LEDs through the I/O ports), the product is monitored in terms of emission. This emission test is in line with the norm IEC61967-2 which specifies the board and the loading of each pin.

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Symbol	Parameter	Conditions	Monitored	Max vs.	Unit
		Conditions	frequency band	16 MHz	
S _{EMI}	Peak level	$V_{DD} = 3.6 \text{ V},$ $T_A = +25 ^{\circ}\text{C},$ SO8N conforming to	0.1 MHz to 30 MHz	TBD	dΒμV
			30 MHz to 130 MHz	TBD	
			130 MHz to 1 GHz	TBD	
		IEC61967-2	SAE EMI Level	TBD	-

Table 50. EMI data (1)

Absolute maximum ratings (electrical sensitivity)

Based on two different tests (ESD and LU) using specific measurement methods, the product is stressed in order to determine its performance in terms of electrical sensitivity. For more details, refer to the application note AN1181.

Electrostatic discharge (ESD)

Electrostatic discharges (a positive then a negative pulse separated by 1 second) are applied to the pins of each sample according to each pin combination. The sample size depends on the number of supply pins in the device (3 parts*(n+1) supply pin). Two models can be simulated: human body model and charge device model. This test conforms to the JESD22-A114A/A115A standard.

Table 51. ESD absolute maximum ratings

Symbol	Ratings	Conditions	Maximum value ⁽¹⁾	Unit	
V _{ESD(HBM)}	Electrostatic discharge voltage (human body model)	T _A = +25 °C	TBD	V	
V _{ESD(CDM)}	Electrostatic discharge voltage (charge device model)	1A- 723 C	TBD		

^{1.} Guaranteed by characterization results.

Static latch-up

• **LU**: 3 complementary static tests are required on 6 parts to assess the latch-up performance. A supply overvoltage (applied to each power supply pin) and a current injection (applied to each input, output and configurable I/O pin) are performed on each sample. This test conforms to the EIA/JESD 78 IC latch-up standard. For more details, refer to the application note AN1181.

Table 52. Electrical sensitivities

Symbol	Parameter	Class
LU Static latch-up class		II

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^{1.} Not tested in production.

9 Package characteristics

Failure analysis and guarantee

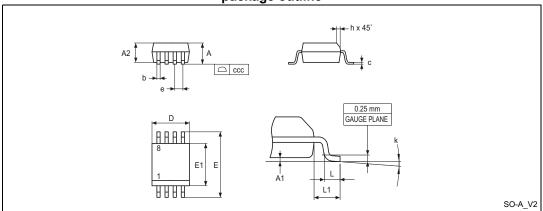
The small number of pins available induces limitations on failure analysis depth in case of isolated symptoms, typically with an impact lower than 0.1%. Please contact your sales office for additional information for any failure analysis. STMicroelectronics will make a feasibility study for investigation based on failure rate and symptom description prior to responsibility endorsement.

9.1 ECOPACK

In order to meet environmental requirements, ST offers these devices in different grades of ECOPACK[®] packages, depending on their level of environmental compliance. ECOPACK[®] specifications, grade definitions and product status are available at: www.st.com. ECOPACK[®] is an ST trademark.

9.2 SO8N package information

Figure 34. SO8N – 8-lead, 4.9 x 6 mm, plastic small outline, 150 mils body width, package outline



1. Drawing is not to scale.

Table 53. SO8N – 8-lead 4.9 x 6 mm, plastic small outline, 150 mils body width, package mechanical data

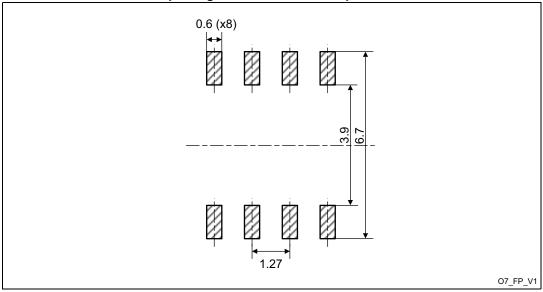
Symbol	millimeters			inches ⁽¹⁾		
	Min.	Тур.	Max.	Min.	Тур.	Max.
Α	-	-	1.750	-	-	0.0689
A1	0.100	-	0.250	0.0039	-	0.0098
A2	1.250	-	-	0.0492	-	-
b	0.280	-	0.480	0.0110	-	0.0189
С	0.170	-	0.230	0.0067	-	0.0091



parating a morning and (community)						
Symbol	millimeters			inches ⁽¹⁾		
	Min.	Тур.	Max.	Min.	Тур.	Max.
D	4.800	4.900	5.000	0.1890	0.1929	0.1969
E	5.800	6.000	6.200	0.2283	0.2362	0.2441
E1	3.800	3.900	4.000	0.1496	0.1535	0.1575
е	-	1.270	-	-	0.0500	-
h	0.250	-	0.500	0.0098	-	0.0197
k	0°	-	8°	0°	-	8°
L	0.400	-	1.270	0.0157	-	0.0500
L1	-	1.040	-	-	0.0409	-
CCC	-	-	0.100	-	-	0.0039

Table 53. SO8N – 8-lead 4.9 x 6 mm, plastic small outline, 150 mils body width, package mechanical data (continued)

Figure 35. SO8N – 8-lead 4.9 x 6 mm, plastic small outline, 150 mils body width, package recommended footprint



^{1.} Dimensions are expressed in millimeters.

Device marking for SO8N - 8-lead 4.9 x 6 mm, plastic small outline, 150 mils body width

The following figure gives an example of topside marking orientation versus pin 1 identifier location.

Other optional marking or inset/upset marks, which identify the parts throughout supply chain operations, are not indicated below.

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^{1.} Values in inches are converted from mm and rounded to four decimal digits.

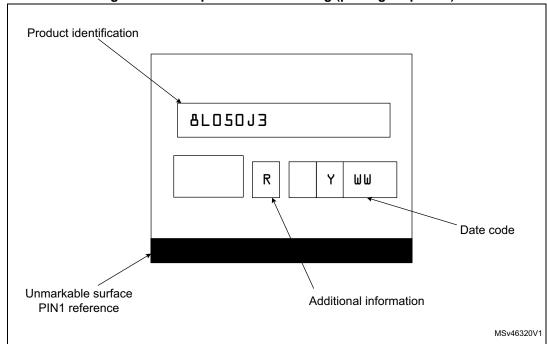


Figure 36. Example of SO8N marking (package top view)

1. Parts marked as ES or E or accompanied by an Engineering Sample notification letter are not yet qualified and therefore not approved for use in production. ST is not responsible for any consequences resulting from such use. In no event will ST be liable for the customer using any of these engineering samples in production. ST's Quality department must be contacted prior to any decision to use these engineering samples to run a qualification activity.

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9.3 Thermal characteristics

The maximum chip junction temperature (T_{Jmax}) must never exceed the values given in *Table 15: General operating conditions on page 50*.

The maximum chip-junction temperature, T_{Jmax} , in degree Celsius, may be calculated using the following equation:

$$T_{Jmax} = T_{Amax} + (P_{Dmax} \times \Theta_{JA})$$

Where:

- T_{Amax} is the maximum ambient temperature in °C
- Θ_{IA} is the package junction-to-ambient thermal resistance in ° C/W
- P_{Dmax} is the sum of P_{INTmax} and $P_{I/Omax}$ ($P_{Dmax} = P_{INTmax} + P_{I/Omax}$)
- P_{INTmax} is the product of I_{DD} and V_{DD}, expressed in Watts. This is the maximum chip internal power.
- P_{I/Omax} represents the maximum power dissipation on output pins Where:

 $P_{I/Omax} = \Sigma \ (V_{OL} * I_{OL}) + \Sigma ((V_{DD} - V_{OH}) * I_{OH}),$ taking into account the actual V_{OL} / I_{OL} and V_{OH} / I_{OH} of the I/Os at low and high level in the application.

Table 54. Thermal characteristics⁽¹⁾

Symbol	Parameter	Value	Unit
$\Theta_{\sf JA}$	Thermal resistance junction-ambient SO8N	102	°C/W

 Thermal resistances are based on JEDEC JESD51-2 with 4-layer PCB in a natural convection environment.

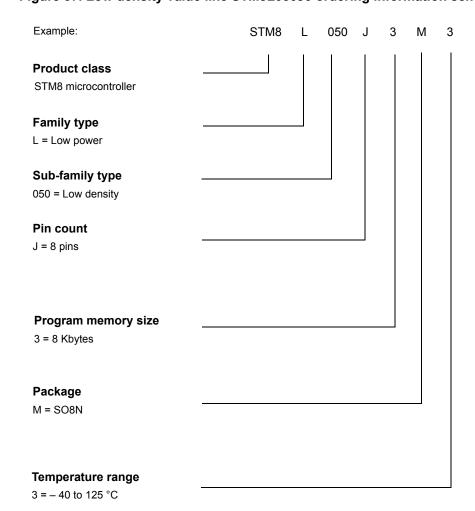


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Ordering information STM8L050J3

10 Ordering information

Figure 37. Low density value line STM8L050J3 ordering information scheme



For a list of available options (for example memory size, package) and orderable part numbers or for further information on any aspect of this device, please contact the ST sales office nearest to you.

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STM8L050J3 Revision history

11 Revision history

Table 55. Document revision history

Date	Revision	Changes	
06-Jun-2017	1	Initial release.	
04-Oct-2017	2	Updated: - Document's classification to "Public" - Section 1: Introduction - Section 3.1: Low-power modes - Section 3.2: Interrupt controller - Section 3.3: Voltage regulator - Section 3.14.1: SPI - Section 3.14.3: USART - Table 4: STM8L050J3 pin description - Note 3 on page 26 - Section 4.1: System configuration options	
04-Jul-2018	3	Updated: - Recommendations for SWIM pin (pin#1) sharing on Section 3.16: Development support	
12-Sep-2018	4	Updated: - Table 42: Comparator 1 characteristics - Table 43: Comparator 2 characteristics - Table 44: ADC1 characteristics	

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